# DATA SHEE

# NY8A051H1

6 I/O 8-bit EPROM-Based MCU

Version 1.1

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# **Revision History**

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# 1. 概述

NY8A051H1 是以EPROM作為記憶體的 8 位元微控制器,專為多IO產品的應用而設計,例如遙控器、風扇/燈光控制或是遊樂器周邊等等。採用CMOS製程並同時提供客戶低成本、高性能等顯著優勢。NY8A051H1 核心建立在RISC精簡指令集架構可以很容易地做編輯和控制,共有55條指令。除了少數指令需要2個時序,大多數指令都是1個時序即能完成,可以讓使用者輕鬆地以程式控制完成不同的應用。因此非常適合各種中低記憶容量但又複雜的應用。

在I/O的資源方面,NY8A051H1 有 6 根彈性的雙向I/O腳,每個I/O腳都有單獨的暫存器控制為輸入或輸出腳。而且每一個I/O腳位都有附加的程式控制功能如上拉或下拉電阻或開漏極(Open-Drain)輸出。此外針對紅外線搖控的產品方面,NY8A051H1內建了可選擇頻率的紅外載波發射口。

NY8A051H1有兩組計時器,可用系統頻率當作一般的計時的應用或者從外部訊號觸發來計數。另外NY8A051H1提供 1 組 8 位元解析度的PWM輸出或者蜂鳴器輸出,可用來驅動馬達、LED、或蜂鳴器等等。

NY8A051H1 採用雙時鐘機制,高速振盪或者低速振盪都由內部RC振盪輸入。在雙時鐘機制下,NY8A051H1 可選擇多種工作模式如正常模式(Normal)、慢速模式(Slow mode)、待機模式(Standby mode) 與睡眠模式(Halt mode)可節省電力消耗延長電池壽命。

在省電的模式下如待機模式(Standby mode)與睡眠模式(Halt mode)中,有多種事件可以觸發中斷喚醒NY8A051H1 進入正常操作模式(Normal)或 慢速模式(Slow mode)來處理突發事件。

#### 1.1 功能

- 寬廣的工作電壓:
  - ≥ 2.0V ~ 5.5V @系統頻率≤8MHz。
  - ▶ 2.2V ~ 5.5V @系統頻率>8MHz。
- 寬廣的工作温度:-40°C~85°C。
- 內建 14 階準確的低電壓偵測電路功能。
- 1Kx14 bits EPROM ∘
- 48 bytes SRAM •
- 6 根可分別單獨控制輸入輸出方向的I/O腳(GPIO)、PB[5:0]。
- PB[3:0]可選擇輸入時使用內建上拉及下拉電阻。
- V<sub>IH</sub>輸入有三種組態可選,分別為 0.8V<sub>DD</sub>、0.6V<sub>DD</sub>及 0.5V<sub>DD</sub>(No Schmitt); V<sub>IL</sub>輸入有三種組態可選,分別為 0.3V<sub>DD</sub>、0.2V<sub>DD</sub>及 0.5V<sub>DD</sub>(No Schmitt)。
- PB[3]內建上拉電阻及輸出高推功能。
- PB[5:0]可選擇上拉電阻或開漏極輸出(Open-Drain)。
- 所有I/O脚輸出可選擇小灌電流(Small Sink Current)或一般灌電流(Normal Sink Current)。

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- 所有I/O腳輸出可選擇小推電流(Small Drive Current)或一般推電流(Normal Drive Current),除PB3外。
- 8 層程式堆棧(Stack)。
- 存取資料有直接或間接定址模式。
- 一組 8 位元上數計時器(Timer0)包含可程式化的頻率預除線路。
- 一組 8 位元下數計時器(Timer1)可選重複載入或連續下數計時。
- 一個8位元的脈衝寬度調變輸出(PWM1)。
- 一個蜂鳴器輸出(BZ1)。
- 38/57KHz紅外線載波頻率可供選擇,同時載波之極性也可以根據數據作選擇。
- 內建上電復位電路(POR)。
- 內建低壓復位功能(LVR)。
- 內建看門狗計時(WDT),可由程式韌體控制開關。
- 雙時鐘機制,系統可以隨時切換高速振盪或者低速振盪。
  - ▶ 高速振盪: I\_HRC (1~20MHz內部高速RC振盪)
  - ▶ 低速振盪: I\_LRC (內部 32KHz低速RC振盪)
- 四種工作模式可隨系統需求調整電流消耗:正常模式(Normal)、慢速模式(Slow mode)、待機模式(Standby mode)與 睡眠模式(Halt mode)。

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- 六種硬體中斷:
  - ➤ Timer0 溢位中斷。
  - ▶ Timer1 借位中斷。
  - > WDT 中斷。
  - ▶ PB 輸入狀態改變中斷。
  - ▶ 外部中斷輸入。
  - ▶ 低電壓偵測中斷。
- NY8A051H1 在待機模式(Standby mode)下的六種喚醒中斷:
  - ➤ Timer0 溢位中斷。
  - Timer1 借位中斷。
  - ➤ WDT 中斷。
  - > PB 輸入狀態改變中斷。
  - ▶ 外部中斷輸入。
  - ▶ 低電壓偵測中斷。
- NY8A051H1 在睡眠模式(Halt mode)下的三種喚醒中斷:
  - ➤ WDT 中斷。
  - ▶ PB 輸入狀態改變中斷。
  - ▶ 外部中斷輸入。



## 1. General Description

NY8A051H1 is an EPROM based 8-bit MCU tailored for I/O based applications like remote controllers, fan/light controller, game controllers, toy and various controllers. NY8A051H1 adopts advanced CMOS technology to provide customers remarkable solution with low cost and high performance benefits. RISC architecture is applied to NY8A051H1 and it provides 55 instructions. All instructions are executed in single instruction cycle except program branch and skip instructions which will take two instruction cycles. Therefore, NY8A051H1 is very suitable for those applications that are sophisticated but compact program size is required.

As NY8A051H1 address I/O type applications, it can provide 6 I/O pins for applications which require abundant input and output functionality. Moreover, each I/O pin may have additional features, like Pull-High/Pull-Low resistor and open-drain output type through programming. Moreover, NY8A051H1 has built-in infrared (IR) carrier generator with selectable IR carrier frequency and polarity for applications which demand remote control feature.

NY8A051H1 also provides 2 sets of timers which can be used as regular timer based on system oscillation or event counter with external trigger clock. Moreover, NY8A051H1 provides 1 set of 8-bit resolution Pulse Width Modulation (PWM) output and buzzer output in order to drive motor/LED and buzzer.

NY8A051H1 employs dual-clock oscillation mechanism, both high oscillation or low oscillation can be derived from internal resistor/capacitor oscillator. Moreover, based on dual-clock mechanism, NY8A051H1 provides kinds of operation mode like Normal mode, Slow mode, Standby mode and Halt mode in order to save power consumption and lengthen battery operation life.

While NY8A051H1 operates in Standby mode and Halt mode, kinds of event will issue interrupt requests and can wake-up NY8A051H1 to enter Normal mode and Slow mode in order to process urgent events.

#### 1.1 Features

- Wide operating voltage range:
  - >  $2.0V \sim 5.5V$  @system clock  $\leq 8MHz$ .
  - > 2.2V ~ 5.5V @system clock > 8MHz.
- Wide operating temperature: -40°C ~ 85°C.
- Built-in 14-level accurate low voltage detection circuit function.
- 1K x 14 bits EPROM.
- 48 bytes SRAM.
- 6 general purpose I/O pins (GPIO), PB[5:0], with independent direction control.
- PB[3:0] has features of Pull-High and Pull-Low resistor for input pin.
- PB[5:0] has features of Pull-High resistor, and open-drain output.
- V<sub>IH</sub> has three types to choose, which are 0.8V<sub>DD</sub>, 0.6V<sub>DD</sub> and 0.5V<sub>DD</sub> (No Schmitt). V<sub>IL</sub> has three types to choose, which are 0.3V<sub>DD</sub>, 0.2V<sub>DD</sub> and 0.5V<sub>DD</sub> (No Schmitt).

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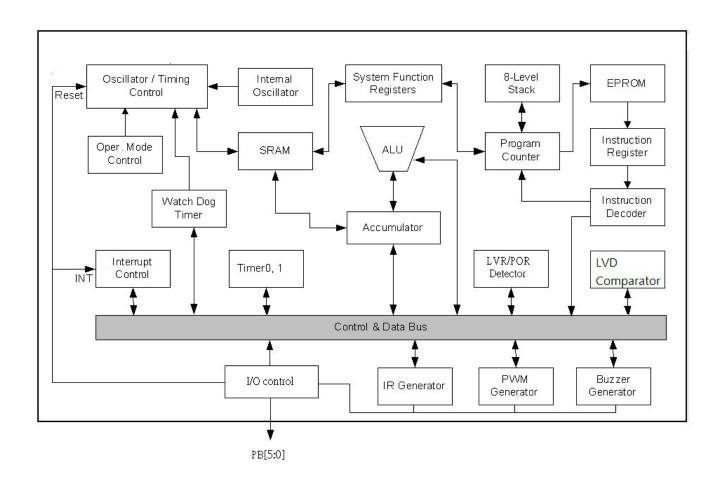
- PB[3] built-in Pull-High resistor and add output high function.
- 8-level hardware Stack.
- Direct and indirect addressing modes for data access.
- One 8-bit up-count timer (Timer0) with programmable pre-scalar.
- One 8-bit reload or continuous down-count timers (Timer1).
- One 8-bit resolution PWM (PWM1) output.
- One buzzer (BZ1) output.
- Selectable 38/57KHz IR carrier frequency and high/low polarity according to data value.
- Built-in Power-On Reset (POR).
- Built-in Low-Voltage Reset (LVR).
- Built-in Watch-Dog Timer (WDT) enabled/disabled by firmware control.
  - Dual-clock oscillation: System clock can switch between high oscillation and low oscillation.
  - High oscillation: I\_HRC (Internal High Resistor/Capacitor Oscillator ranging from 1M~20MHz)

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- > Low oscillation: I LRC (Internal 32KHz oscillator)
- Four kinds of operation mode to reduce system power consumption:
  - > Normal mode, Slow mode, Standby mode and Halt mode.
- Six hardware interrupt events:
  - Timer0 overflow interrupt.
  - > Timer1 underflow interrupt.
  - > WDT timeout interrupt.
  - > PB input change interrupt.
  - > External interrupt.
  - > LVD interrupt.
- Six interrupt events to wake-up NY8A051H1 from Standby mode:
  - > Timer0 overflow interrupt.
  - > Timer1 underflow interrupt.
  - > WDT timeout interrupt.
  - PB input change interrupt.
  - > External interrupt.
  - > LVD interrupt.
- Three interrupt events to wake-up NY8A051H1 from Halt mode:
  - > WDT timeout interrupt.
  - > PB input change interrupt.
  - > External interrupt.



# 1.2 Block Diagram



# 1.3 NY8A051H 與 NY8A051H1 與 NY8A051J 的主要差異

Item	Function	NY8A051H	NY8A051H1	NY8A051J
1	PWM	1	1	3
2	Comparator analog input pins	PBO/PB1	PBO/PB1	PB0/PB1/ PB4/PB5
3	LVD Voltage Select	16-level	14-level	14-level
4	Timer1 w/o prescaler	-	-	V

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# 1.4 Pin Assignment

NY8A051H1 provides two kinds of package type which are SOP8 and SOT23-6.



Figure 1 Package pin assignment

# 1.5 Pin Description

Pin Name	I/O	Description
PB0 INT CMP+ SDI	I/O	PB0 is a bidirectional I/O pin and can be as comparator analog input pins. PB0 is input pin of external interrupt when EIS=1 & INTIE=1. PB0 can be comparator non-inverse input. PB0 can be programming pad SDI.
PB1 IR CMP- SDO	I/O	PB1 is a bidirectional I/O pin and can be as comparator analog input pins.  If IR mode is enabled, this pin is IR carrier output.  PB1 can be comparator inverse input.  PB1 can be programming pad SDO.
PB2 EX_CKI PWM1 BZ1 SCK Comparator	I/O	PB2 is a bidirectional I/O pin and can be as comparator analog output pin. PB2 can also be timer clock source EX_CKI. PB2 can also be PWM output. PB2 can also be BUZZER output. PB2 can also be programming pad SCK. PB2 can also be comparator output.
PB3 RSTb Vpp	I/O	PB3 is a bidirectional I/O pin. PB3 can be reset pin RSTb. If RSTb pin is low, it will reset NY8A051H1. PB3 can be programming pad VPP.
PB4 F <sub>INST</sub> OUT	I/O	PB4 is a bidirectional I/O pin. PB4 also can be output of instruction clock.
PB5	I/O	PB5 is a bidirectional I/O pin.
VDD	-	Positive power supply.
vss	-	Ground.

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# 2. Memory Organization

NY8A051H1 memory is divided into two categories: one is program memory and the other is data memory.

#### 2.1 Program Memory

The program memory space of NY8A051H1 is 1K words. Therefore, the Program Counter (PC) is 10-bit wide in order to address any location of program memory.

Some locations of program memory are reserved as interrupt entrance. Power-On Reset vector is located at 0x000. Software interrupt vector is located at 0x001. Internal and external hardware interrupt vector is located at 0x008.

NY8A051H1 provides instruction CALL, GOTOA, CALLA to address 256 location of program space. NY8A051H1 provides instruction GOTO to address 512 location of program space. NY8A051H1 also provides instructions LCALL and LGOTO to address any location of program space.

When a call or interrupt is happening, next ROM address is written to top of the stack, when RET, RETIA or RETIE instruction is executed, the top of stack data is read and load to PC.

NY8A051H1 program ROM address 0x3FE~0x3FF are reserved space, if user tries to write code in these addresses will get unexpected false functions.

NY8A051H1 program ROM address 0x00E~0x00F are preset rolling code can be released and used as normal program space.

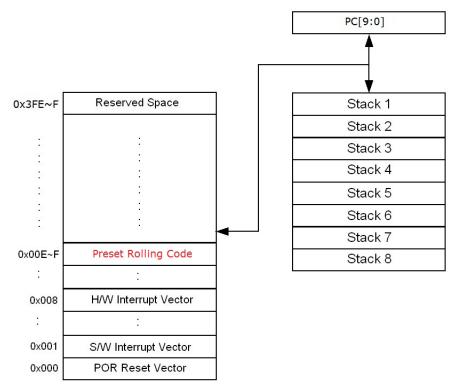


Figure 2 Program Memory Address Mapping



#### 2.2 Data Memory

According to instructions used to access data memory, the data memory can be divided into three kinds of categories: one is R-page Special-function Register (SFR) + General Purpose Register (GPR), another is F-page SFR and the other is S-page SFR. GPR are made of SRAM and user can use them to store variables or intermediate results.

R-page data memory is divided into 4 banks and can be accessed directly or indirectly through a SFR register which is File Select Register (FSR). FSR[7:6] are used as Bank register BK[1:0] to select one bank out of the 4 banks.

R-page register can be divided into addressing mode: direct addressing mode and indirect addressing mode.

The indirect addressing mode of data memory access is described in the following graph. This indirect addressing mode is implied by accessing register INDF. The bank selection is determined by FSR[7:6] and the location selection is from FSR[5:0].

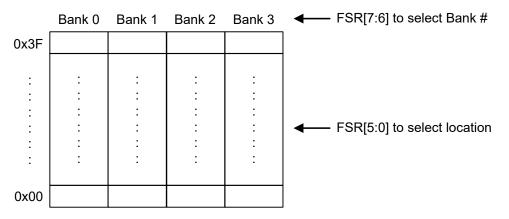


Figure 3 Indirect Addressing Mode of Data Memory Access

The direct addressing mode of data memory access is described below. The bank selection is determined by FSR[7:6] and the location selection is from instruction op-code[5:0] immediately.

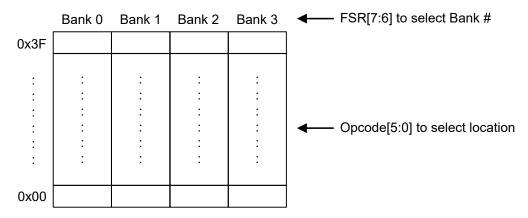


Figure 4 Direct Addressing Mode of Data Memory Access

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R-page SFR can be accessed by general instructions like arithmetic instructions and data movement instructions. The R-page SFR occupy address from 0x0 to 0xF of Bank 0. However, the same address range of Bank 1, Bank 2 and Bank 3 are mapped back to Bank 0. In other words, R-page SFR physically existed at Bank 0. The GPR physically occupy address from 0x10 to 0x3F of Bank and other banks in address from 0x10 to 0x3F are mapped back as the Table 1 shows.

The NY8A051H1 register name and address mapping of R-page SFR are described in the following table.

FSR[7:6]	00	01	10	11				
Address	(Bank 0)	(Bank 1)	(Bank 2)	(Bank 3)				
0x0	INDF							
0x1	TMR0							
0x2	PCL							
0x3	STATUS							
0x4	FSR							
0x5	-							
0x6	PORTB	The same mapping as Bank 0						
0x7	-							
0x8	PCON							
0x9	BWUCON							
0xA	PCHBUF							
0xB	BPLCON							
0xC	BPHCON							
0xD	-							
0xE	INTE							
0xF	INTF							
0x10 ~ 0x1F	General Purpose							
OX 10 % OX 1F	Register	Unused er						
0x20 ~ 0x3F	General Purpose		Unused					
3A20 0A01	Register	Ollused						

Table 1 R-page SFR Address Mapping

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F-page SFR can be accessed only by instructions IOST and IOSTR. S-page SFR can be accessed only by instructions SFUN and SFUNR. FSR[7:6] bank select bits are ignored while F-page and S-page register is accessed. The register name and address mapping of F-page and S-page are depicted in the following table.



SFR Category Address	F-page SFR	S-page SFR
0x0	-	TMR1
0x1	-	T1CR1
0x2	-	T1CR2
0x3	-	PWM1DUTY
0x4	-	PS1CV
0x5	-	BZ1CR
0x6	IOSTB	IRCR
0x7	-	TBHP
0x8	-	TBHD
0x9	-	-
0xA	PS0CV	-
0xB	-	-
0xC	BODCON	-
0xD	-	-
0xE	CMPCR	-
0xF	PCON1	OSCCR

Table 2 F-page and S-page SFR Address Mapping

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# 3. Function Description

This chapter will describe the detailed operations of NY8A051H1.

#### 3.1 R-page Special Function Register

#### 3.1.1 INDF (Indirect Addressing Register)

Name	SFR Type	Addr.	Bit7	Bit6	Bit5	Bit4	Bit3	Bit2	Bit1	Bit0
INDF	R	0x0				INDF	[7:0]			
	R/W Propert	у				R	W			
	Initial Value					XXXX	XXXX			

The register INDF is not physically existed and it is used as indirect addressing mode. Any instruction accessing INDF actually accesses the register pointed by register FSR

#### 3.1.2 TMR0 (Timer0 Register)

Name	SFR Type	Addr.	Bit7	Bit6	Bit5	Bit4	Bit3	Bit2	Bit1	Bit0
TMR0	R	0x1				TMR	0[7:0]			
	R/W Property					R	W			
	Initial Value					XXXX	XXXX			

When read the register TMR0, it actually read the current running value of Timer0.

Write the register TMR0 will change the current value of Timer0.

Timer0 clock source can be from instruction clock F<sub>INST</sub>, or from external pin EX\_CKI, or from Low Oscillator Frequency according to T0MD and configuration word setting.

#### 3.1.3 PCL (Low Byte of PC[9:0])

Name	SFR Type	Addr.	Bit7	Bit6	Bit5	Bit4	Bit3	Bit2	Bit1	Bit0
PCL	R	0x2				PCL	[7:0]			
	R/W Property					R	W			
	Initial Value					0x	:00			

The register PCL is the least significant byte (LSB) of 10-bit PC. PCL will be increased by one after one instruction is executed except some instructions which will change PC directly. The high byte of PC, i.e. PC[9:8], is not directly accessible. Update of PC[9:8] must be done through register PCHBUF.

For GOTO instruction, PC[8:0] is from instruction word and PC[9] is loaded from PCHBUF[1]. For CALL instruction, PC[7:0] is from instruction word and PC[9:8] is loaded from PCHBUF[1:0]. Moreover the next PC address, i.e. PC+1, will push onto top of Stack. For LGOTO instruction, PC[9:0] is from instruction word.

For LCALL instruction, PC[9:0] is from instruction word. Moreover the next PC address, i.e. PC+1, will push onto top of Stack.



#### 3.1.4 STATUS (Status Register)

Name	SFR Type	Addr.	Bit7	Bit6	Bit5	Bit4	Bit3	Bit2	Bit1	Bit0
STATUS	R	0x3	GP7	GP6	GP5	/TO	/PD	Z	DC	С
R	/W Property		R/W	R/W	R/W	R/W <sup>(*2)</sup>	R/W <sup>(*1)</sup>	R/W	R/W	R/W
I	nitial Value	•	0	0	0	1	1	X	X	X

The register STATUS contains result of arithmetic instructions and reasons to cause reset.

#### C: Carry/Borrow bit

C=1, carry is occurred for addition instruction or borrow is not occurred for subtraction instruction.

C=0, carry is not occurred for addition instruction or borrow is occurred for subtraction instruction.

DC: Half Carry/half Borrow bit

DC=1, carry from the 4th LSB is occurred for addition instruction or borrow from the 4th LSB is not occurred for subtraction instruction.

DC=0, carry from the 4th LSB is not occurred for addition instruction or borrow from the 4th LSB is occurred for subtraction instruction.

#### Z: Zero bit

Z=1, result of logical operation is zero.

Z=0, result of logical operation is not zero.

/PD: Power down flag bit

/PD=1, after power-up or after instruction CLRWDT is executed.

/PD=0, after instruction SLEEP is executed.

/TO: Time overflow flag bit

/TO=1, after power-up or after instruction CLRWDT or SLEEP is executed.

/TO=0, WDT timeout is occurred.

GP7, GP6, GP5: General purpose read/write register bit.

(\*1) can be cleared by sleep instruction.

(\*2) can be set by CLRWDT instruction.

#### 3.1.5 FSR (Register File Selection Register)

Name	SFR Type	Addr.	Bit7	Bit7 Bit6 Bit5 Bit4 Bit3 Bit2 Bit1 B							
FSR	R	0x4	BK[	1:0]	FSR[5:0]						
	R/W Property					R	W				
	Initial Value		0	0	Х	Х	Х	Х	Х	Х	

**FSR[5:0]:** Select one register out of 64 registers of specific Bank.

BK[1:0] must be 00. For NY8A051H1, bank register is not used, because there's only one bank



#### 3.1.6 PortB (PortB Data Register)

Name	SFR Type	Addr.	Bit7	Bit6	Bit5	Bit4	Bit3	Bit2	Bit1	Bit0
PortB	R	0x6	GP7	GP6	PB5	PB4	PB3	PB2	PB1	PB0
	R/W Propert	ty				R	W			
	Initial Value	)	Data la	atch value	is xxxxx	x, read va	lue is xxx	xxx port	value(PB	5~PB0)

While reading PortB, it will get the status of the specific pin if that pin is configured as input pin. However, if that pin is configured as output pin, whether it will get the status of the pin or the value of the corresponding output data latch is depend on the configuration word RD\_OPT. While writing to PortB, data is written to PB's output data latch.

GP7, GP6: General purpose read/write register bit.

#### 3.1.7 PCON (Power Control Register)

Name	SFR Type	Addr.	Bit7	Bit6	Bit5	Bit4	Bit3	Bit2	Bit1	Bit0
PCON	R	0x8	WDTEN	EIS	LVDEN	GP4	LVREN	CMPEN	GP1	GP0
	R/W Property	′				R/	W			
	Initial Value		1	0	0	0	1	0	0	0

**GP5~0:** General read/write register bits.

**CMPEN:** Enable/disable CMP

CMPEN=1, enable CMP.

CMPEN=0, disable CMP.

LVREN: Enable/disable LVR.

LVREN=1, enable LVR.

LVREN=0, disable LVR.

LVDEN: Enable/disable LVD.

LVDEN=1, enable LVD.

LVDEN=0, disable LVD.

EIS: External interrupt select bit

EIS=1, PB0 is external interrupt.

EIS=0, PB0 is GPIO.

WDTEN: Enable/disable WDT.

WDTEN=1, enable WDT.

WDTEN=0, disable WDT.

#### 3.1.8 BWUCON (PortB Wake-up Control Register)

Name	SFR Type	Addr.	Bit7	Bit6	Bit5	Bit4	Bit3	Bit2	Bit1	Bit0
BWUCON	R	0x9	-	-	WUPB5	WUPB4	WUPB3	WUPB2	WUPB1	WUPB0
R/W	Property	/	-	-	R/W	R/W	R/W	R/W	R/W	R/W
Initi	al Value		Х	Х	1	1	1	1	1	1

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**WUPBx:** Enable/disable PBx wake-up function,  $0 \le x \le 5$ .

WUPBx=1, enable PBx wake-up function. WUPBx=0, disable PBx wake-up function.

# 3.1.9 PCHBUF (High Byte of PC)

Name	SFR Type	Addr.	Bit7	Bit6	Bit5	Bit4	Bit3	Bit2	Bit1	Bit0
PCHBUF	R	0xA	-	ı	ı	ı	ı	GP5	PCHE	BUF[1:0]
R	/W Property		-	-	-	-	-	R/W		W
I	Initial Value				Х	Х	Х	0		00

**PCHBUF[1:0]:** Buffer of the 9<sup>th</sup> bit, 8<sup>th</sup> bit of PC. It will be used as backup register for interrupt.

GP5: General read/write register bit.

## 3.1.10 BPLCON (PortB Pull-Low Resistor Control Register)

Name	SFR Type	Addr.	Bit7	Bit6	Bit5	Bit4	Bit3	Bit2	Bit1	Bit0
BPLCON	R	0xB	/PLPB3	/PLPB2	/PLPB1	/PLPB0	-	-	-	-
R	/W Property		R/W	R/W	R/W	R/W	-	-	-	-
I	nitial Value		1	1	1	1	Х	Х	Х	Х

**/PLPBx:** Disable/enable PBx Pull-Low resistor,  $0 \le x \le 3$ .

/PLPBx=1, disable PBx Pull-Low resistor.

/PLPBx=0, enable PBx Pull-Low resistor.

#### 3.1.11 BPHCON (PortB Pull-High Resistor Control Register)

Name	SFR Type	Addr	Bit7	Bit6	Bit5	Bit4	Bit3	Bit2	Bit1	Bit0
BPHCON	R	0xC	ı	ı	/PHPB5	/PHPB4	/PHPB3	/PHPB2	/PHPB1	/PHPB0
R/W	Property	y	-	-	R/W	R/W	R/W	R/W	R/W	R/W
Initia	al Value		Х	Х	1	1	1	1	1	1

**/PHPBx:** Disable/enable PBx Pull-High resistor,  $0 \le x \le 5$ .

/PHPBx=1, disable PBx Pull-High resistor.

/PHPBx=0, enable PBx Pull-High resistor.

#### 3.1.12 INTE (Interrupt Enable Register)

Name	SFR Type	Addr.	Bit7	Bit6	Bit5	Bit4	Bit3	Bit2	Bit1	Bit0
INTE	R	0xE	-	WDTIE	-	LVDIE	T1IE	INTIE	PBIE	T0IE
	R/W Property	,	-	R/W	-	R/W	R/W	R/W	R/W	R/W
	Initial Value		Х	0	Х	0	0	0	0	0



**T0IE:** Timer0 overflow interrupt enable bit.

T0IE=1, enable Timer0 overflow interrupt.

T0IE=0, disable Timer0 overflow interrupt.

PBIE: PortB input change interrupt enable bit.

PBIE=1, enable PortB input change interrupt.

PBIE=0, disable PortB input change interrupt.

INTIE: External interrupt enable bit.

INTIE=1, enable external interrupt.

INTIE=0, disable external interrupt.

T1IE: Timer1 underflow interrupt enable bit.

T1IE=1, enable Timer1 underflow interrupt.

T1IE=0, disable Timer1 underflow interrupt.

LVDIE: Low-voltage detector interrupt enable bit.

LVDIE=1, enable low-voltage detector interrupt.

LVDIE=0, disable low-voltage detector interrupt.

WDTIE: WDT timeout interrupt enable bit.

WDTIE=1, enable WDT timeout interrupt.

WDTIE=0, disable WDT timeout interrupt.

## 3.1.13 INTF (Interrupt Flag Register)

Name	SFR Type	Addr.	Bit7	Bit6	Bit5	Bit4	Bit3	Bit2	Bit1	Bit0
INTF	R	0xF	-	WDTIF	-	LVDIF	T1IF	INTIF	PBIF	TOIF
	R/W Property		-	R/W	-	R/W	R/W	R/W	R/W	R/W
Ini	tial Value(note	·*)	Х	0	Х	0	0	0	0	0

T0IF: Timer0 overflow interrupt flag bit.

T0IF=1, Timer0 overflow interrupt is occurred.

T0IF must be clear by firmware.

**PBIF:** PortB input change interrupt flag bit.

PBIF=1, PortB input change interrupt is occurred.

PBIF must be clear by firmware.

INTIF: External interrupt flag bit.

INTIF=1, external interrupt is occurred.

INTIF must be clear by firmware.

T1IF: Timer1 underflow interrupt flag bit.

T1IF=1, Timer1 underflow interrupt is occurred.

T1IF must be clear by firmware.

LVDIF: Low-voltage detector interrupt flag bit.

LVDIF=1, Low-voltage detector interrupt is occurred.

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LVDIF must be clear by firmware.



WDTIF: WDT timeout interrupt flag bit.

WDTIF=1, WDT timeout interrupt is occurred.

WDTIF must be clear by firmware.

Note: When corresponding INTE bit is not enabled, the read interrupt flag is 0.

### 3.2 T0MD Register

T0MD is a readable/writeable register which is only accessed by instruction T0MD / T0MDR.

Name	SFR Type	Addr.	Bit7	Bit6	Bit5	Bit4	Bit3	Bit2	Bit1	Bit0
TOMD		-	LCKTM0	INTEDG	T0CS	T0CE	PS0WDT	PS	SOSEL[2	2:0]
	R/W Property	/				R/W				
Ini	tial Value(not	e*)	0	0	1	1	1		111	

**PS0SEL[2:0]:** Prescaler0 dividing rate selection. The rate depends on Prescaler0 is assigned to Timer0 or WDT. When Prescaler0 is assigned to WDT, the dividing rate is dependent on which timeout mechanism is selected.

	Dividing Rate								
PS0SEL[2:0]	PS0WDT=0	PS0WDT=1	PS0WDT=1						
	(Timer0)	(WDT Reset)	(WDT Interrupt)						
000	1:2	1:1	1:2						
001	1:4	1:2	1:4						
010	1:8	1:4	1:8						
011	1:16	1:8	1:16						
100	1:32	1:16	1:32						
101	1:64	1:32	1:64						
110	1:128	1:64	1:128						
111	1:256	1:128	1:256						

Table 3 Prescaler0 Dividing Rate

**PS0WDT:** Prescaler0 assignment.

PS0WDT=1, Prescaler0 is assigned to WDT.

PS0WDT=0, Prescaler0 is assigned to Timer0.

Note: Always set PS0WDT and PS0SEL[2:0] before enabling watchdog or timer interrupt, or reset or interrupt may be falsely triggered.

**T0CE:** Timer0 external clock edge selection.

T0CE=1, Timer0 will increase one while high-to-low transition occurs on pin EX\_CKI.

T0CE=0, Timer0 will increase one while low-to-high transition occurs on pin EX\_CKI.

Note: T0CE is also applied to Low Oscillator Frequency as timer0 clock source condition.

T0CS: Timer0 clock source selection.



T0CS=1, External clock on pin EX\_CKI or I\_LRC is selected.

T0CS=0, Instruction clock FINST is selected.

**INTEDG:** Edge selection of external interrupt.

INTEDG=1, INTIF will be set while rising edge occurs on pin PB0.

INTEDG=0, INTIF will be set while falling edge occurs on pin PB0.

**LCKTM0:** When T0CS=1, timer 0 clock source can be optionally selected to be low-frequency oscillator.

T0CS=0, Instruction clock F<sub>INST</sub> is selected as timer0 clock source.

T0CS=1, LCKTM0=0, external clock on pin EX\_CKI is selected as timer0 clock source.

T0CS=1, LCKTM0=1, I\_LRC output replaces pin EX\_CKI as timer0 clock source.

Note: For more detail descriptions of timer0 clock source select, please see timer0 section.

# 3.3 F-page Special Function Register

#### 3.3.1 IOSTB (PortB I/O Control Register)

Name	SFR Type	Addr.	Bit7	Bit6	Bit5	Bit4	Bit3	Bit2	Bit1	Bit0
IOSTB	F	0x6	-	-	IOPB5	IOPB4	IOPB3	IOPB2	IOPB1	IOPB0
R	/W Property		-	-	R/W	R/W	R/W	R/W	R/W	R/W
	Initial Value		Х	Х	1	1	1	1	1	1

**IOPBx:** PBx I/O mode selection,  $0 \le x \le 5$ .

IOPBx=1, PBx is input mode.

IOPBx=0, PBx is output mode.

#### 3.3.2 PS0CV (Prescaler0 Counter Value Register)

Name	SFR Type	Addr.	Bit7	Bit6	Bit5	Bit4	Bit3	Bit2	Bit1	Bit0
PS0CV	F	0xA				PS0C	V[7:0]			
F	R/W Property					ı	₹			
	1	1	1	1	1	1	1	1		

While reading PS0CV, it will get current value of Prescaler0 counter.

#### 3.3.3 BODCON (PortB Open-Drain Control Register)

Name	SFR Type	Addr	Bit7	Bit6	Bit5	Bit4	Bit3	Bit2	Bit1	Bit0
BODCON	F	0xC	-	ı	ODPB5	ODPB4	ODPB3	ODPB2	ODPB1	ODPB0
R/\	R/W Property			-	R/W	R/W	R/W	R/W	R/W	R/W
Initial Value			X	X	0	0	0	0	0	0

**ODPBx:** Enable/disable open-drain of PBx,  $0 \le x \le 5$ .

ODPBx=1, enable open-drain of PBx.

ODPBx=0, disable open-drain of PBx.



# 3.3.4 CMPCR (Comparator voltage select Control Register)

Name	SFR Type	Addr.	Bit7	Bit6	Bit5	Bit4	Bit3	Bit2	Bit1	Bit0
CMPCR	F	0xE	GP7	RBIAS_H	RBIAS_L	CMPF_INV	PS1	PS0	NS1	NS0
R/W Property R/W						R/W				
	Initial Value		0	0	0	0	1	0	1	0

NS[1:0]: Comparator inverting input select.

NS[1:0]	Inverting input
00	PB1
01	-
10	Bandgap (0.65V)
11	Vref

PS[1:0]: Comparator non-inverting input select

PS[1:0]	Non-inverting input
00	PB0
01	
10	Vref
11	

CMPF\_INV: Comparator output inverse control bit.

CMPF INV = 1, Inverse comparator output.

CMPF\_INV = 0, Non-inverse comparator output.

RBIAS\_L, RBIAS\_H: Set corresponding voltage reference levels

(please refer to chapter 3.10.1)

#### 3.3.5 PCON1 (Power Control Register1)

Name	SFR Type	Addr.	Bit7	Bit6	Bit5	Bit4	Bit3	Bit2	Bit1	Bit0
PCON1	F	0xF	GIE	LVDOUT	LVDS3	LVDS2	LVDS1	LVDS0	GP1	T0EN
R/	R/W Property		R/W <sup>(1*)</sup>	R	R/W	R/W	R/W	R/W	R/W	R/W
Ir	itial Value	!	0	Х	1	1	1	1	0	1

**T0EN:** Enable/disable Timer0.

T0EN=1, enable Timer0.

T0EN=0, disable Timer0.

GIE: Global interrupt enable bit.

GIE=1, enable all unmasked interrupts.

GIE=0, disable all interrupts.

LVDOUT: Low voltage detector output, read-only.

LVDS3~0: Select one of the 14 LVD voltages.



LVDS[3:0]	LVDL Voltage	LVDH Voltage
0001	2.23V	2.26V
0010	2.41V	2.45V
0011	2.84V	2.88V
0100	2.93V	2.98V
0101	3.03V	3.08V
0110	3.30V	3.35V
0111	3.62V	3.68V
1000	3.93V	3.98V
1010	4.07V	4.12V
1011	2.62V	2.66V
1100	4.15V	4.21V
1101	3.19V	3.23V
1110	3.48V	3.53V
1111	3.76V	3.81V

Table 4 LVD voltage select

LVDL means that VDD voltage High transit to Low. LVDH means that VDD voltage Low transit to High.

GP1: General purpose read/write register.

(1\*): set by instruction ENI, clear by instruction DISI, read by instruction IOSTR.

# 3.4 S-page Special Function Register

#### 3.4.1 TMR1 (Timer1 Register)

Name	SFR Type	Addr.	Bit7	Bit6	Bit5	Bit4	Bit3	Bit2	Bit1	Bit0
TMR1	8	0x0	TMR1[7:0]							
	R/W Property		R/W							
	Initial Value		XXXXXXXX							

When reading register TMR1, it will obtain current value of 8-bit down-count Timer1. When writing register TMR1, it will both write data to timer1 reload register and update Timer1 current content.

# 3.4.2 T1CR1 (Timer1 Control Register1)

Name	SFR Type	Addr.	Bit7	Bit6	Bit5	Bit4	Bit3	Bit2	Bit1	Bit0
T1CR1	S	0x1	PWM10EN	PWM1OAL	-	-	-	T1OS	T1RL	T1EN
R	W Property		R/W	R/W	-	-	-	R/W	R/W	R/W
lı	nitial Value		0	0	Х	Х	Х	0	0	0

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This register is used to configure Timer1 functionality.



T1EN: Enable/disable Timer1.

T1EN=1, enable Timer1.

T1EN=0, disable Timer1.

T1RL:Configure Timer1 down-count mechanism while Non-Stop mode is selected (T1OS=0).

T1RL=1, initial value is reloaded from reload register TMR1.

T1RL=0, continuous down-count from 0xFF when underflow is occurred.

T10S: Configure Timer1 operating mode while underflow is reached.

T1OS=1, One-Shot mode. Timer1 will count once from the initial value to 0x00.

T1OS=0, Non-Stop mode. Timer1 will keep down-count after underflow.

T10S	T1RL	Timer1 Down-Count Functionality						
	0	Timer1 will count from reload value down to 0x00.						
0	U	When underflow is reached, 0xFF is reloaded and continues down-count.						
0	1	Timer1 will count from reload value down to 0x00.						
0	Į	When underflow is reached, reload value is reloaded and continues to down-count.						
1	.,	Timer1 will count from initial value down to 0x00.						
'	1 x	When underflow is reached, Timer1 will stop down-count.						

Table 5 Timer1 Functionality

**PWM1OAL:** Define PWM1 output active state.

PWM1OAL=1, PWM1 output is active low.

PWM1OAL=0, PWM1 output is active high.

PWM10EN: Enable/disable PWM1 output.

PWM10EN=1, PWM1 output will be present on PB2.

PWM10EN=0, PB2 is GPIO.

#### 3.4.3 T1CR2 (Timer1 Control Register2)

Name	SFR Type	Addr.	Bit7	Bit6	Bit5	Bit4	Bit3	Bit2	Bit1	Bit0
T1CR2	S	0x2	-	-	T1CS	T1CE	/PS1EN	P	S1SEL[2	:0]
	R/W Propert	у	-	-	R/W	R/W	R/W	R/W	R/W	R/W
	Initial Value		Х	Х	1	1	1	1	1	1

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This register is used to configure Timer1 functionality.

**PS1SEL[2:0]:** Prescaler1 dividing rate selection.

PS1SEL[2:0]	Dividing Rate
000	1:2
001	1:4
010	1:8
011	1:16
100	1:32



PS1SEL[2:0]	Dividing Rate
101	1:64
110	1:128
111	1:256

Table 6 Prescaler1 Dividing Rate

Note: Always set PS1SEL[2:0] at /PS1EN=1, or interrupt may be falsely triggered.

/PS1EN: Disable/enable Prescaler1.

/PS1EN=1, disable Prescaler1.

/PS1EN=0, enable Prescaler1.

T1CE: Timer1 external clock edge selection.

T1CE=1, Timer1 will decrease one while high-to-low transition occurs on pin EX\_CKI.

T1CE=0, Timer1 will decrease one while low-to-high transition occurs on pin EX\_CKI.

T1CS: Timer1 clock source selection.

T1CS=1, External clock on pin EX\_CKI is selected.

T1CS=0, Instruction clock is selected.

# 3.4.4 PWM1DUTY (PWM1 Duty Register)

Name	SFR Type	Addr.	Bit7	Bit6	Bit5	Bit4	Bit3	Bit2	Bit1	Bit0
PWM1DUTY	S	0x3	PWM1DUTY[7:0]							
RΛ	N Property	W								
In	itial Value	XXXXXXX								

This register is write-only. After Timer1 is enabled and start down-count, PWM1 output will keep at inactive state. While Timer1 value is equal to PWM1DUTY, PWM1 output will become active state until underflow is occurred.

Moreover, the reload value of Timer1 stored on register TMR1 is used to define the PWM1 frame rate and register PWM1DUTY is used to define the duty cycle of PWM1.

# 3.4.5 PS1CV (Prescaler1 Counter Value Register)

Name	SFR Type	Addr.	Bit7	Bit6	Bit5	Bit4	Bit3	Bit2	Bit1	Bit0
PS1CV	8	0x4	PS1CV[7:0]							
	R/W Property	1					₹			
	Initial Value		1 1 1 1 1 1						1	

While reading PS1CV, it will get current value of Prescaler1 counter.



# 3.4.6 BZ1CR (Buzzer1 Control Register)

Name	SFR Type	Addr.	Bit7	Bit6	Bit5	Bit4	Bit3	Bit2	Bit1	Bit0
BZ1CR S 0x5			BZ1EN	-	-	-	BZ1FSEL[3:0]			
ı	R/W Property	W	-	-	-		W			
	Initial Value	0	Х	Х	Х	1	1	1	1	

BZ1FSEL[3:0]:Frequency selection of BZ1 output.

D745051 [0.0]	BZ1 Frequenc	cy Selection
BZ1FSEL[3:0]	Clock Source	Dividing Rate
0000		1:2
0001		1:4
0010	Prescaler1 output	1:8
0011		1:16
0100		1:32
0101		1:64
0110		1:128
0111		1:256
1000		Timer1 bit 0
1001		Timer1 bit 1
1010		Timer1 bit 2
1011	Timer1 euteut	Timer1 bit 3
1100	Timer1 output	Timer1 bit 4
1101		Timer1 bit 5
1110		Timer1 bit 6
1111		Timer1 bit 7

Table 7 Buzzer1 Output (PB2) Frequency Selection

BZ1EN: Enable/Disable BZ1 output.

BZ1EN=1, enable Buzzer1.

BZ1EN=0, disable Buzzer1.

# 3.4.7 IRCR (IR Control Register)

Name	SFR Type	Addr.	Bit7	Bit6	Bit5	Bit4	Bit3	Bit2	Bit1	Bit0
IRCR	S	0x6	-	-	-	-	1	IRCSEL	IRF57K	IREN
I	R/W Property	-	-	-	-	-	W	W	W	
	Initial Value			Х	Х	Х	Х	0	0	0

IREN: Enable/Disable IR carrier output.

IREN=1, enable IR carrier output.



IREN=0, disable IR carrier output.

IRF57K: Selection of IR carrier frequency.

IRF57K=1, IR carrier frequency is 57KHz.

IRF57K=0, IR carrier frequency is 38KHz.

IRCSEL: Polarity selection of IR carrier.

IRCSEL=0, IR carrier will be generated when I/O pin data is 1.

IRCSEL=1, IR carrier will be generated when I/O pin data is 0.

#### Note:

1. Only high oscillation (FHOSC) (See section 3.12) can be used as IR clock source.

2. Division ratio for different oscillation type.

OSC. Type	57KHz	38KHz	Conditions
High IRC	64	96	HIRC mode (the input to IR module is set to 4MHz no matter what system clock is)

Table 8 Division ratio for different oscillation type

#### 3.4.8 TBHP (Table Access High Byte Address Pointer Register)

Name	SFR Type	Addr.	Bit7	Bit6	Bit5	Bit4	Bit3	Bit2	Bit1	Bit0
TBHP	S	0x7	-	-	-	-	-	-	TBHP1	TBHP0
1	R/W Property			-	-	-	-	-	R/W	R/W
	Initial Value		Х	Х	Х	Х	Х	Х	Х	Х

When instruction CALLA, GOTOA or TABLEA is executed, the target address is constituted by TBHP[1:0] and ACC. ACC is the Low Byte of PC[9:0] and TBHP[1:0] is the high byte of PC[9:0].

#### 3.4.9 TBHD (Table Access High Byte Data Register)

Name	SFR Type	Addr.	Bit7	Bit6	Bit5	Bit4	Bit3	Bit2	Bit1	Bit0
TBHD	S	0x8	-	-	TBHD5	TBHD4	TBHD3	TBHD2	TBHD1	TBHD0
F	R/W Property				R	R	R	R	R	R
Initial Value			Х	Х	Х	Х	Х	Х	Х	Х

When instruction TABLEA is executed, high byte of content of addressed ROM is loaded into TBHD[5:0] register. The Low Byte of content of addressed ROM is loaded to ACC.

## 3.4.10 OSCCR (Oscillation Control Register)

Name	SFR Type	Addr.	Bit7	Bit6	Bit5	Bit4	Bit3	Bit2	Bit1	Bit0
OSCCR	8	0xF	-	CMPOEN	-	-	ОРМЕ	0[1:0]	STPHOSC	SELHOSC
R	W Property	-	R/W	-	-	R/W		R/W	R/W	
I	nitial Value	Х	0	Х	Х	00	)	0	1	

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**SELHOSC:** Selection of system oscillation (F<sub>OSC</sub>).



SELHOSC=1, Fosc is high-frequency oscillation (Fhosc).

SELHOSC=0, Fosc is low-frequency oscillation (FLOSC).

**STPHOSC:** Disable/enable high-frequency oscillation (F<sub>HOSC</sub>).

STPHOSC=1, FHOSC will stop oscillation and be disabled.

STPHOSC=0, FHOSC keep oscillation.

**CMPOEN:** Comparator output enable / disable

CMPOEN=1, Comparator output enable

CMPOEN=0, Comparator output disable

**OPMD[1:0]:** Selection of operating mode.

OPMD[1:0]	Operating Mode
00	Normal mode
01	Halt mode
10	Standby mode
11	reserved

Table 9 Selection of Operating Mode by OPMD[1:0]

Note: STPHOSC cannot be changed with SELHOSC or OPMD at the same time. STPHOSC cannot be changed with OPMD at the same time during SELHOSC=1.

#### 3.5 I/O Port

NY8A051H1 provide 6 I/O pins which are PB[5:0]. User can read/write these I/O pins through register PORTB. Each I/O pin has a corresponding register bit to define it is input pin or output pin. Register IOSTB[5:0] define the input/output direction of PB[5:0].

When an I/O pin is configured as input pin, it may have Pull-High resistor or Pull-Low resistor which is enabled or disabled through registers. Register BPHCON[5:0] are used to enable or disable Pull-High resistor of PB[5:0]. Register BPLCON[7:4] are used to enable or disable Pull-Low resistor of PB[3:0].

When an I/O pin is configured as output pin, there is a corresponding and individual register to select as Open-Drain output pin. Register BODCON[5:0] determine PB[5:0] is Open-Drain or not.

The summary of Pad I/O feature is listed in the table below.

	Feature	PB[3:0]	PB[5:4]
lpput	Pull-High Resistor	V	V
Input	Pull-Low Resistor	V	Х
Output	Open-Drain	V	V

Table 10 Summary of Pad I/O Feature

The level change on each I/O pin of PB may generate interrupt request. Register BWUCON[5:0] will select which I/O pin of PB may generate this interrupt. As long as any pin of PB is selected by corresponding bit of



BWUCON, the register bit PBIF (INTF[1]) will set to 1 if there is a level change occurred on any selected pin. An interrupt request will occur and interrupt service routine will be executed if register bit PBIE (INTE[1]) and GIE (PCON1[7]) are both set to 1.

There is one external interrupt provided by NY8A051H1. When register bit EIS (PCON[6]) is set to 1, PB0 is used as input pin for external interrupt.

Note: When PB0 is both set as level change operation and external interrupt, the external interrupt will have higher priority, and the PB0 level change operation will be disabled. But PB5~PB1 level change function are not affected.

NY8A051H1 can provide IR carrier generation. IR carrier generation is enabled by register bit IREN (IRCR[0]) and carrier will be present on a PB1 pin.

PB3 can be used as external reset input determined by a configuration word. When an active-low signal is applied to PB3, it will cause NY8A051H1 to enter reset process.

When NY8A051H1 is in Normal mode or Standby mode, instruction clock is observable on PB4 if a configuration word is enabled.

Moreover, PB2 can be timer 0 external clock source EX\_CKI if T0MD T0CS=1 and LCK\_TM0=0. PB2 can be timer 1 external clock source if T1CS=1.

Moreover, PB2 can be PWM output if T1CR1[7] PWM10EN=1 and corresponding PB.2 configuration word. PB2 can also be Buzzer output if BZ1CR[7] BZ1EN=1 and corresponding PB.2 configuration word.

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# 3.5.1 Block Diagram of IO Pins

IO\_SEL: Set pad attribute as input or output.

WRITE\_EN: Write data to pad.

READ\_EN: Read pad.

OD\_EN: Enable open-Drain.

PULLUP\_ENB: Enable Pull-High.

PULLDOWN\_EN: Enable Pull-Low.

RD\_TYPE: select Read pin or read latch.

EIS: External interrupt function enable.

INTEDGE: External interrupt edge select.

EX\_INT: External interrupt signal.

WUB: Port B wake-up enable. SET\_PBIF: Port B wake-up flag.

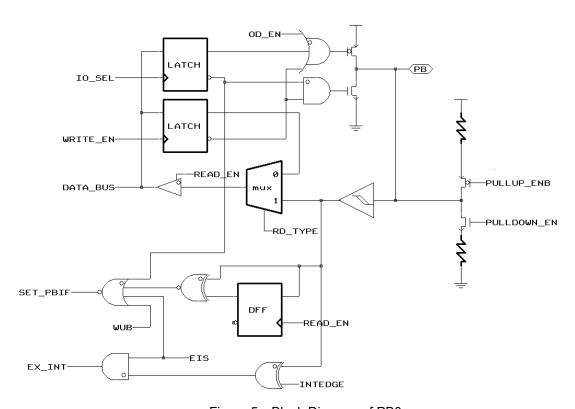


Figure 5 Block Diagram of PB0

Please refer to the chapter 6. Electrical Characteristics for RPH and RPL.

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WRITE\_EN: Write data to pad.

READ\_EN: Read pad.

OD\_EN: Enable open-Drain.

PULLUP\_ENB: Enable Pull-High.

PULLDOWN\_EN: Enable Pull-Low.

RD\_TYPE: Select read pin or read latch.

IREN: IR function enable.

IRDT: IR data.

WUB: Port B wake-up enable.
SET\_PBIF: Port B wake-up flag.

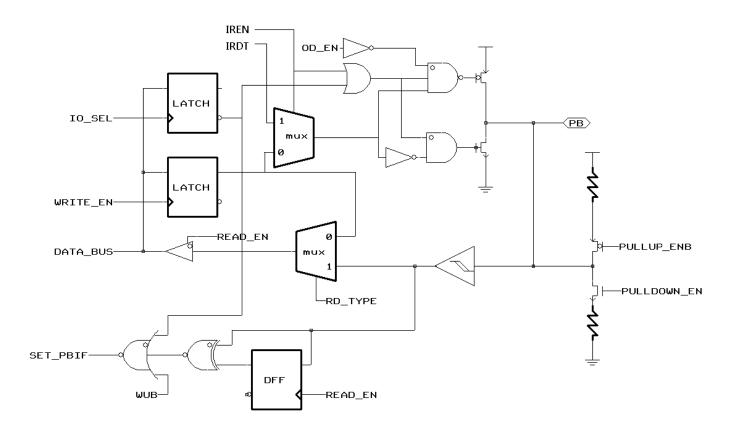


Figure 6 Block Diagram of PB1

Please refer to the chapter 6. Electrical Characteristics for  $R_{\text{PH}}$  and  $R_{\text{PL}}$ .



WRITE\_EN: Write data to pad.

READ\_EN: Read pad.

OD\_EN: Enable open-Drain.

PULLUP\_ENB: Enable Pull-High.

PULLDOWN\_EN: Enable Pull-Low.

RD\_TYPE: Select read pin or read latch.

PBEN: PWM/BUZZER enable.

PBDT: PWM/BUZZER data.

WUB: Port B wake-up enable.

SET\_PBIF: Port B wake-up flag.

EX CKI: External clock input.

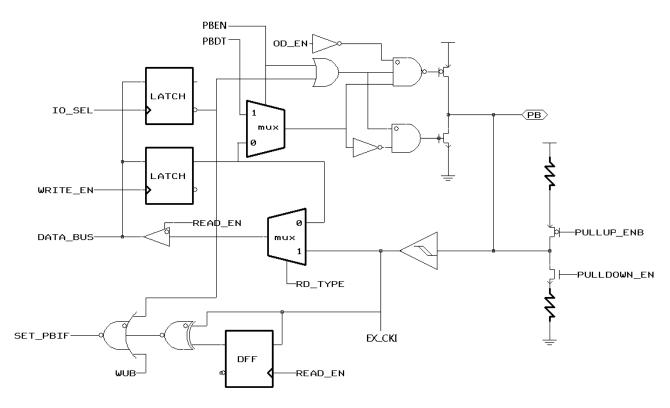


Figure 7 Block Diagram of PB2

Please refer to the chapter 6. Electrical Characteristics for RPH and RPL.



WRITE\_EN: Write data to pad.

READ\_EN: Read pad.

OD\_EN: Enable open-Drain.

PULLUP\_ENB: Enable Pull-High.

PULLDOWN\_EN: Enable Pull-Low.

RD\_TYPE: Select read pin or read latch.

PBEN: PWM/BUZZER enable.

PBDT: PWM/BUZZER data.

WUB: Port B wake-up enable.

SET\_PBIF: Port B wake-up flag.

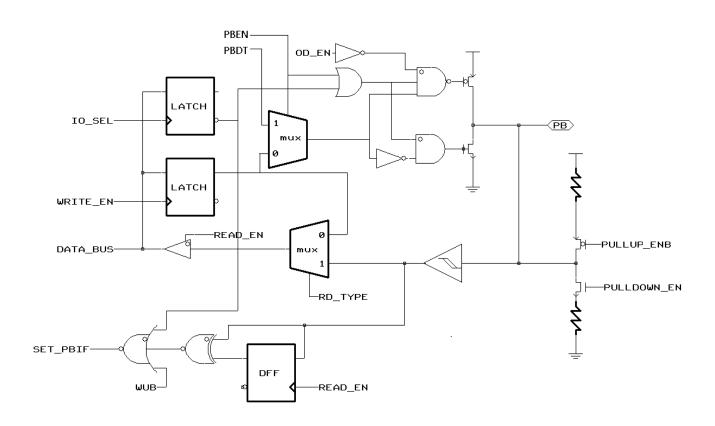


Figure 8 Block Diagram of PB3

Please refer to the chapter 6. Electrical Characteristics for  $R_{\text{PH}}$  and  $R_{\text{PL}}.$ 

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WRITE\_EN: Write data to pad.

READ\_EN: Read pad.

OD\_EN: Enable open-Drain.

PULLUP\_ENB: Enable Pull-High.

RD\_TYPE: Select read pin or read latch.

WUB: Port B wake-up enable.

SET\_PBIF: Port B wake-up flag.

DATA\_BUS

DEFF

READ\_EN

DEFF

READ\_EN

DEFF

READ\_EN

DEFF

READ\_EN

Figure 9 Block Diagram of PB4/PB5

Please refer to the chapter 6. Electrical Characteristics for RPH and RPL

#### 3.6 Timer0

Timer0 is an 8-bit up-count timer and its operation is enabled by register bit T0EN (PCON1[0]). Writing to Timer0 will set its initial value. Reading from Timer0 will show its current count value.

The clock source to Timer0 can be from instruction clock, external pin EX\_CKI or low speed clock Low Oscillator Frequency according to register bit T0CS and LCK\_TM0 (T0MD[5] and T0MD[7]). When T0CS is 0, instruction

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clock is selected as Timer0 clock source. When T0CS is 1 and LCK\_TM0 is 0, EX\_CKI is selected as Timer0 clock source. When T0CS is 1 and LCK\_TM0 is 1 (and Timer0 source must set to 1), Low Oscillator Frequency (I\_LRC) output is selected. Summarized table is shown below. (Also check Figure. 10)

Timer0 clock source	TOCS	LCKTM0	Timer0 source
Instruction clock	0	Х	Х
EX_CKI	1	0	Х
		Х	0
I_LRC	1	1	1

Table 11 Summary of Timer0 clock source control

Moreover the active edge of EX\_CKI or Low Oscillator Frequency to increase Timer0 can be selected by register bit T0CE (T0MD[4]). When T0CE is 1, high-to-low transition on EX\_CKI or Low Oscillator Frequency will increase Timer0. When T0CE is 0, low-to-high transition on EX\_CKI or Low Oscillator Frequency will increase Timer0.

Before Timer0 clock source is supplied to Timer0, it can be divided by Prescaler0 if register bit PS0WDT (T0MD[3]) is clear to 0. When writing 0 to PS0WDT by instruction, Prescaler0 is assigned to Timer0 and Prescaler0 will be clear after this instruction is executed. The dividing rate of Prescaler0 is determined by register bits PS0SEL[2:0] which is from 1:2 to 1:256.

Before entering Timer0, the Timer0 clock source synchronize with instruction clock in default. If EX\_CKI or Low Oscillator Frequency is used as Timer0 clock source, care must be taken that their frequency can not exceed instruction clock frequency, or missing count may happen. When Low Oscillator Frequency is both used as Timer0 clock source and instruction clock, NY8A051H1 must assign prescaler0 to Timer0 and the prescaler0 dividing ratio must be no less than 4. There's a configuration word (EX\_CKI to Inst. Clock) which can relieve this constraint. When this option is set to Async, the Timer0 clock source does not synchronize with the instruction clock, so the input frequency of EX\_CKI can be higher than the instruction clock. The maximum frequency the EX\_CKI can input is depended on process variation.

When Timer0 is overflow, the register bit T0IF (INTF[0]) will be set to 1 to indicate Timer0 overflow event is occurred. If register bit T0IE (INTE[0]) and GIE are both set to 1, interrupt request will occur and interrupt service routine will be executed. T0IF will not be clear until firmware writes 0 to T0IF.

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The block diagram of Timer0 and WDT is shown in the figure below.



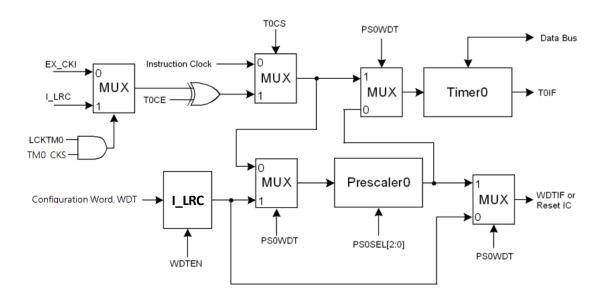


Figure 10 Block Diagram of Timer0 and WDT

### 3.7 Timer1/PWM1/Buzzer1

Timer1 is an 8-bit down-count timer with Prescaler1 whose dividing rate is programmable. The output of Timer1 can be used to generate PWM1 output and Buzzer1 output. A write to the Timer1 will both write to a timer1 reload register (T1rld) and timer1 counter. A read to the timer1 will show the content of the Timer1 current count value.

The block diagram of Timer1 is shown in the figure below.

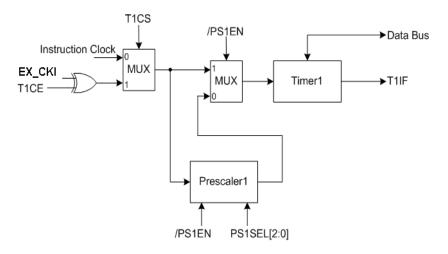


Figure 11 Block Diagram of Timer1

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The operation of Timer1 can be enabled or disabled by register bit T1EN (T1CR1[0]). After Timer1 is enabled, its clock source can be instruction clock or pin EX\_CKI which is determined by register bit T1CS (T1CR2[5]). When T1CS is 1, EX\_CKI is selected as clock source. When T1CS is 0, instruction clock is selected as clock source. When EX\_CKI is selected, the active edge to decrease Timer1 is determined by register bit T1CE (T1CR2[4]).



When T1CE is 1, high-to-low transition on EX\_CKI will decrease Timer1. When T1CE is 0, low-to-high transition on EX\_CKI will decrease Timer1. The selected clock source can be divided further by Prescaler1 before it is applied to Timer1. Prescaler1 is enabled by writing 0 to register bit /PS1EN (T1CR2[3]) and the dividing rate is from 1:2 to 1:256 determined by register bits PS1SEL[2:0] (T1CR2[2:0]). Current value of Prescaler1 can be obtained by reading register PS1CV.

Timer1 provide two kinds of operating mode: one is One-Shot mode and the other is Non-Stop mode. When register bit T1OS (T1CR1[2]) is 1, One-Shot mode is selected. Timer1 will count down once from initial value stored on register TMR1 to 0x00, i.e. underflow is occurred. When register bit T1OS (T1CR1[2]) is 0, Non-Stop mode is selected. When underflow is occurred, there are two selections to start next down-count which is determined by register bit T1RL (T1CR1[1]). When T1RL is 1, the initial value stored on register TMR1 will be restored and start next down-count from this initial value. When T1RL is 0, Timer1 will start next down-count from 0xFF.

When Timer1 is underflow, the register bit T1IF (INTF[3]) will be set to 1 to indicate Timer1 underflow event is occurred. If register bit T1IE (INTE[3]) and GIE are both set to 1, interrupt request will occur and interrupt service routine will be executed. T1IF will not be clear until firmware writes 0 to T1IF.

The timing chart of Timer1 is shown in the following figure.

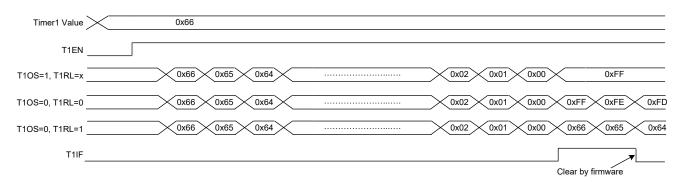


Figure 12 Timer1 Timing Chart

The PWM1 output can be available on I/O pin PB2 when register bit PWM10EN (T1CR1[7]) is set to 1 and configuration word PB.2 is PWM. When PWM10EN=1, PB2 will become output pin automatically. The active state of PWM1 output is determined by register bit PWM10AL (T1CR1[6]). When PWM10AL is 1, PWM1 output is active low. When PWM10AL is 0, PWM1 output is active high. Moreover, the duty cycle and frame rate of PWM1 are both programmable. The duty cycle is determined by register PWM1DUTY. When PWM1DUTY is 0, PWM1 output will be never active. When PWM1DUTY is 0xFF, PWM1 output will be active for 255 Timer1 input clocks. The frame rate is determined by TMR1 initial value. Therefore, PWM1DUTY value must be less than or equal to TMR1. The block diagram of PWM1 is illustrated in the following figure.

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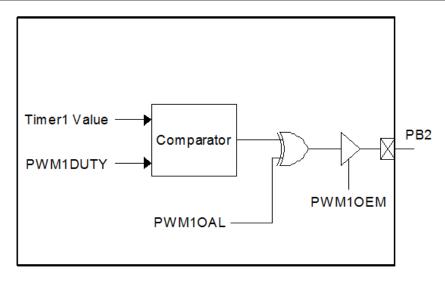


Figure 13 PWM1 Block Diagram

The Buzzer1 output (BZ1) can be available on I/O pin PB2, when register bit BZ1EN (BZ1CR1[7]) is set to 1 and corresponding configuration word PB.2 is BUZZER. When BZ1EN is set to 1, PB2 will become output pin automatically. The frequency of BZ1 can be derived from Timer1 output or Prescaler1 output and dividing rate is determined by register bits BZ1FSEL[3:0] (BZ1CR[3:0]). When BZ1FSEL[3] is 0, Prescaler1 output is selected to generate BZ1 output. When BZ1FSEL[3] is 1, Timer1 output is selected to generate BZ1 output. The dividing rate can be from 1:2 to 1:256 in order to generate all kinds of frequency. The block diagram of Buzzer1 is illustrated in the following figure.

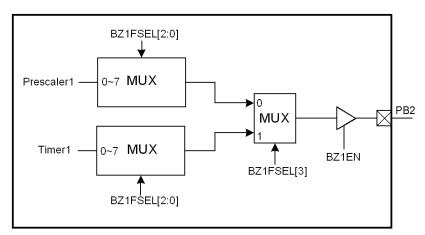


Figure 14 Buzzer1 Block Diagram

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#### 3.8 IR Carrier

The IR carrier will be generated after register bit IREN (IRCR[0]) is set to 1. Moreover, PB1 will become output pin automatically. When IREN is clear to 0, PB1 will become general I/O pin as it was configured.

The IR carrier frequency is selectable by register bit IRF57K (IRCR[1]). When IRF57K is 1, IR carrier frequency is 57KHz. When IRF57K is 0, IR carrier frequency is 38KHz.

The active state (polarity) of IR carrier is selectable according to PB1 output data. When register bit IRCSEL (IRCR[2]) is 1, IR carrier will be present on pin PB1 when its output data is 0. When register bit IRCSEL (IRCR[2]) is 0, IR carrier will be present on pin PB1 when its output data is 1. The polarity of IR carrier is shown in the following figure.

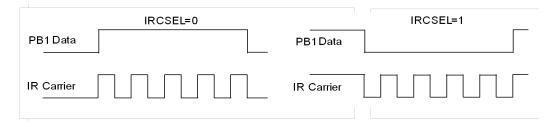


Figure 15 Polarity of IR Carrier vs. Output Data

# 3.9 Comparator-Related Functions

#### 3.9.1 Function Overview

- Voltage Comparator;
- Low Voltage Detection (LVD);
- Built-in resistor voltage divider module to monitor power supply voltage VDD;
- LVD & Comparator interrupt

### 3.9.2 Voltage Comparator

NY8A051H1 provides voltage comparator and internal reference voltage with various analog comparing mode. The comparator non-inverting and inverting input can share with GPIO.

CMPEN (register PCON[2]) is used to enable and disable comparator. When CMPEN=0(default), comparator is disabled. When CMPEN=1, the comparator is enabled. In halt mode the comparator is disabled automatically. The structure of comparator is shown in the following figure:

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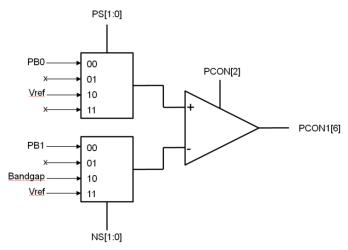


Figure 16 Comparator block diagram

The non-inverting input of the comparator is determined by PS[1:0] (register CMPCR[3:2]).

The table is shown below

PS[1:0]	Non-inverting input
00	PB0
01	
10	Vref
11	

Table 12 Non-inverting input select

The inverting input of the comparator is determined by NS[1:0] (register CMPCR[1:0]).

The table is shown below

NS[1:0]	Inverting input
00	PB1
01	
10	Bandgap (0.65V)
11	Vref

Table 13 Inverting input select

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There are two ways to get the comparator output result: one is through register polling, the other is through probing output pad. Comparator output can be polled by LVDOUT (register PCON1[6]). To probe comparator output at output pad, set CMPOE (register OSCCR[6]) to 1, then PB2 will be the real-time state of the comparator output.



# 3.9.3 Comparator Reference Voltage (Vref)

The internal reference voltage Vref is built by series resistance to provide different level of reference voltage. RBIAS\_H and RBIAS\_L are used to select the maximum and minimum values of Vref, and LVDS[3:0] are used to select one of 32 voltage levels.

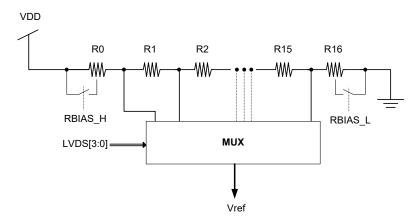


Figure 17 Vref hardware connection

The Vref is determined by RBIAS\_H, RBIAS\_L and LVDS[3:0]. The LVDS[3:0] is used to select one out of 32 reference voltages, the table shown below. (ex: 0.505\*VDD = 2.525V@VDD=5V)

Condition							
LV	/D	Trim					
RBIAS[H:L]	LVDS[3:0]	VDD=5V V <sub>in-</sub> = V <sub>REF</sub> (V)					
10 0	000b	0.505*VDD					
10 0	001b	0.459*VDD					
10 0	010b	0.421*VDD					
10 0	011b	0.362*VDD					
10 0	100b	0.349*VDD					
10 0	101b	0.338*VDD					
10 0	110b	0.311*VDD					
10 0	111b	0.283*VDD					
10 10	000b	0.261*VDD					
10 10	001b	0.523*VDD					
10 10	010b	0.251*VDD					
10 1	011b	0.389*VDD					
10 1	100b	0.245*VDD					
10 1	101b	0.322*VDD					



Condition							
L\	/D	Trim					
RBIAS[H:L]	LVDS[3:0]	VDD=5V V <sub>in-</sub> = V <sub>REF</sub> (V)					
10 1	110b	0.294*VDD					
10 1	111b	0.273*VDD					
01 0	000b	0.248*VDD					
01 0	001b	0.219*VDD					
01 0	010b	0.194*VDD					
01 0	011b	0.156*VDD					
01 0	100b	0.148*VDD					
01 0	101b	0.140*VDD					
01 0	110b	0.123*VDD					
01 0	111b	0.105*VDD					
01 1	000b	0.091*VDD					
01 1	001b	0.260*VDD					
01 1	010b	0.085*VDD					
01 1	011b	0.174*VDD					
01 1	100b	0.081*VDD					
01 1	101b	0.130*VDD					
01 1	110b	0.112*VDD					
01 1	111b	0.099*VDD					

Table 14 The reference voltage Vref selection table

Note: The deviation of Vref is ±0.1V.

Based on an internal reference voltage (Vref) generated by a series resistor divider, the comparator can be used to monitor the supply voltage. When the inverting input is set to the internal bandgap reference (0.65V) and the non-inverting input is connected to the internal resistor divider output (Vref), the comparator compares the supply voltage against the configured threshold.

- The comparator output is 0 when the supply voltage is below the threshold.
- The comparator output is 1 when the supply voltage is above the threshold.

The voltage threshold can be adjusted by configuring RBIAS\_H, RBIAS\_L, and LVDS[3:0]. The available monitoring levels are detailed in the table below:

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		T
RBIAS[H:L]	LVRS[3:0]	$V_{DD}(V)$
11	1000	4.625
01	0100	4.613
01	0011	4.359
11	1111	4.210
00	1100	4.122
00	1010	4.035
11	0111	3.943
00	1000	3.905
01	1011	3.892
00	1111	3.739
11	1110	3.640
00	0111	3.623
00	1110	3.481
01	0010	3.448

DDIACILI 1	LVDC[2.0]	V (V)
RBIAS[H:L]	LVRS[3:0]	$V_{DD}(V)$
11	0110	3.334
00	0110	3.325
00	1101	3.207
11	1101	3.119
00	0101	3.069
01	0001	3.047
00	0100	2.966
11	0101	2.882
00	0011	2.868
11	0100	2.716
01	0000	2.691
00	1011	2.677
10	1100	2.585
01	1001	2.572

RBIAS[H:L]	LVRS[3:0]	$V_{DD}(V)$
11	0011	2.566
10	1010	2.530
00	0010	2.478
10	1000	2.449
10	1111	2.345
11	1011	2.292
00	0001	2.282
10	0111	2.272
10	1110	2.183
00	0000	2.094
10	0110	2.085
11	0010	2.030
00	1001	2.028
10	1101	2.011

Table 15 Reference Voltage select table

# 3.9.4 Low Voltage Detection (LVD)

NY8A051H1 low voltage detector (LVD) built-in precise band-gap reference for accurately detecting VDD level. Built-in 14-stage precise low-voltage detection circuit, allowing users to directly select the desired detection voltage point. If LVDEN(register PCON[5])=1 and VDD voltage value falls below LVD voltage which is selected by LVDS[3:0] as table shown below, the LVD output will become low. If the LVD interrupt is enabled, the LVD interrupt flag will be high and if GIE=1 it will force the program to execute interrupt service routine. Moreover, LVD real-state output can be polled by register PCON1[6]. The following is LVD block diagram:

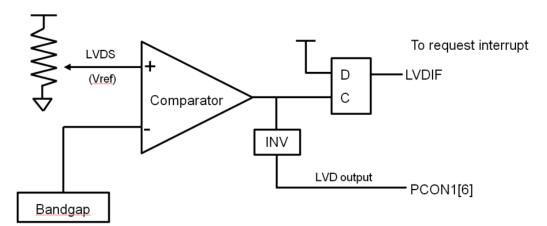


Figure 18 LVD block diagram



The following table is LVD voltage select table.

LVDS[3:0]	LVDL Voltage	LVDH Voltage		
0001	2.23V	2.26V		
0010	2.41V	2.45V		
0011	2.84V	2.88V		
0100	2.93V	2.98V		
0101	3.03V	3.08V		
0110	3.30V	3.35V		
0111	3.62V	3.68V		
1000	3.93V	3.98V		
1010	4.07V	4.12V		
1011	2.62V	2.66V		
1100	4.15V	4.21V		
1101	3.19V	3.23V		
1110	3.48V	3.53V		
1111	3.76V	3.81V		

Table 16 LVD voltage select

#### The LVD control flow is as the following:

Step1: Select LVD voltage by RBIAS[H:L] & LVDS[3:0]

Step2: Set CMPCR = 0x0A

Step3: Set PCON[5]=1 (enable LVD)
Step4: Check LVD status by PCON1[6]

Note: If LVD voltage LVDS[3:0] is changed, user must wait at least 50us(@Fhosc=1MHz) to get correct LVD status by PCON1[6]

# 3.9.5 LVD / Comparator Interrupt

When VDD level falls below LVD voltage, LVD flag will go from high to low, and set the register bit LVDIF=1. And when the comparator result differs from the previous value, a comparator interrupt is generated. This interrupt request will be serviced if LVDIE and GIE are set to 1.

# 3.10 Watch-Dog Timer (WDT)

There is an on-chip free-running oscillator in NY8A051H1 which is used by WDT. As this oscillator is independent of other oscillation circuits, WDT may still keep working during Standby mode and Halt mode.

WDT can be enabled or disabled by a configuration word. When WDT is enabled by configuration word, its operation still can be controlled by register bit WDTEN (PCON[7]) during program execution. Moreover, the

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mechanism after WDT time-out can reset NY8A051H1 or issue an interrupt request which is determined by another configuration word. At the same time, register bit /TO (STATUS[4]) will be clear to 0 after WDT time-out.

The baseline of WDT time-out period can be 3.5 ms, 15 ms, 60 ms or 250 ms which is determined by two configuration words. The time-out period can be lengthened if Prescaler0 is assigned to WDT. Prescaler0 will be assigned to WDT by writing 1 to register bit PS0WDT. The dividing rate of Prescaler0 for WDT is determined by register bits PS0SEL[2:0] and depends on WDT time-out mechanism. The dividing rate is from 1:1 to 1:128 if WDT time-out will reset NY8A051H1 and dividing rate is from 1:2 to 1:256 if WDT time-out will interrupt NY8A051H1.

When Prescaler0 is assigned to WDT, the execution of instruction CLRWDT will clear WDT, Prescaler0 and set /TO flag to 1.

If user selects interrupt for WDT time-out mechanism, register bit WDTIF (INTF[6]) will set to 1 after WDT is expired. It may generate an interrupt request if register bit WDTIE (INTE[6]) and GIE both set to 1. WDTIF will not be clear until firmware writes 0 to WDTIF.

## 3.11 Interrupt

NY8A051H1 provide two kinds of interrupt: one is software interrupt and the other is hardware interrupt. Software interrupt is caused by execution of instruction INT. There are 6 hardware interrupts:

- Timer0 overflow interrupt.
- Timer1 underflow interrupt.
- WDT timeout interrupt.
- PB input change interrupt.
- External interrupt...
- LVD interrupt

GIE is global interrupt enable flag. It has to be 1 to enable hardware interrupt functions. GIE can be set by ENI instruction and clear to 0 by DISI instruction.

After instruction INT is executed, no matter GIE is set or clear, the next instruction will be fetched from address 0x001. At the same time, GIE will be clear to 0 by NY8A051H1 automatically. This will prevent nested interrupt from happening. The last instruction of interrupt service routine of software interrupt has to be RETIE. Execution of this instruction will set GIE to 1 and return to original execution sequence.

While any of hardware interrupts is occurred, the corresponding bit of Interrupt Flag Register INTF will be set to 1. This bit will not be clear until firmware writes 0 to this bit. Therefore user can obtain information of which event causes hardware interrupt by polling register INTF. Note that only when the corresponding bit of Interrupt Enable register INTE is set to 1, will the corresponding interrupt flag be read. And if the corresponding bit of Interrupt Enable Register INTE is set to 1 and GIE is also 1, hardware interrupt will occur and next instruction will be fetched from 0x008. At the same time, the register bit GIE will be clear by NY8A051H1 automatically. Instruction

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RETIE has to be the last instruction of interrupt service routine which will set GIE to 1 and return to original execution sequence.

# 3.11.1 Timer0 Overflow Interrupt

Timer0 overflow (from 0x00 to 0xFF) will set register bit T0IF. This interrupt request will be serviced if T0IE and GIE are set to 1.

# 3.11.2 Timer1 Underflow Interrupt

Timer1 underflow (from 0xFF to 0x00) will set register bit T1IF. This interrupt request will be serviced if T1IE and GIE are set to 1.

# 3.11.3 WDT Timeout Interrupt

When WDT is timeout and the configuration word selects WDT timeout will generate interrupt request, it will set register bit WDTIF. This interrupt request will be serviced if WDTIE and GIE are set to 1.

## 3.11.4 PB Input Change Interrupt

When PBx,  $0 \le x \le 5$ , is configured as input pin and corresponding register bit WUPBx is set to 1, a level change on these selected I/O pin(s) will set register bit PBIF. This interrupt request will be serviced if PBIE and GIE are set to 1. Note when PB0 is both set as level change interrupt and external interrupt, the external interrupt flag EIS will disable PB0 level change operation.

### 3.11.5 External Interrupt

According to the configuration of EIS=1 and INTEDG, the selected active edge on I/O pin PB0 will set register bit INTIF and this interrupt request will be served if INTIE and GIE are set to 1.

#### 3.11.6 LVD / Comparator Interrupt

When VDD level falls below LVD voltage, LVD flag will go from high to low, and set the register bit LVDIF=1. This interrupt request will be serviced if LVDIE and GIE are set to 1.

# 3.12 Oscillation Configuration

Because NY8A051H1 is a dual-clock IC, there are high oscillation (FHOSC) and low oscillation (FLOSC) which can be selected as system oscillation (FOSC). The oscillators which could be used as FHOSC are internal high RC oscillator (I HRC). The oscillators which could be used as FLOSC are internal low RC oscillator (I LRC).

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- (1) STPHOSC(OSCCR[1])=1 will stop Fhosc
- (2) Fhosc will be disabled automatically at Halt mode

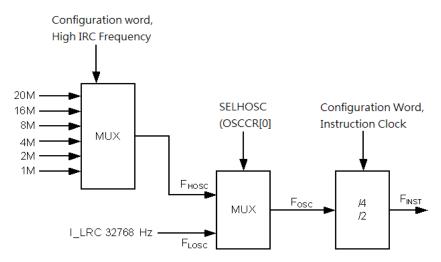


Figure 19 Oscillation Configuration of NY8A051H1

I\_HRC output frequency is determined by three configuration words and it can be 1M, 2M, 4M, 8M, 16M or 20MHz.

When I\_LRC is selected, its frequency is centered on 32768Hz.

Either F<sub>HOSC</sub> or F<sub>LOSC</sub> can be selected as system oscillation F<sub>OSC</sub> according to the value of register bit SELHOSC (OSCCR[0]). When SELHOSC is 1, F<sub>HOSC</sub> is selected as F<sub>OSC</sub>. When SELHOSC is 0, F<sub>LOSC</sub> is selected as F<sub>OSC</sub>. Once F<sub>OSC</sub> is determined, the instruction clock F<sub>INST</sub> can be F<sub>OSC</sub>/2 or F<sub>OSC</sub>/4 according to value of a configuration word.

#### 3.13 Operating Mode

NY8A051H1 provides four kinds of operating mode to tailor all kinds of application and save power consumptions. These operating modes are Normal mode, Slow mode, Standby mode and Halt mode. Normal mode is designated for high-speed operating mode. Slow mode is designated for low-speed mode in order to save power consumption. At Standby mode, NY8A051H1 will stop almost all operations except Timer0/Timer1/WDT in order to wake-up periodically. At Halt mode, NY8A051H1 will sleep until external event or WDT trigger IC to wake-up.

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The block diagram of four operating modes is described in the following figure.



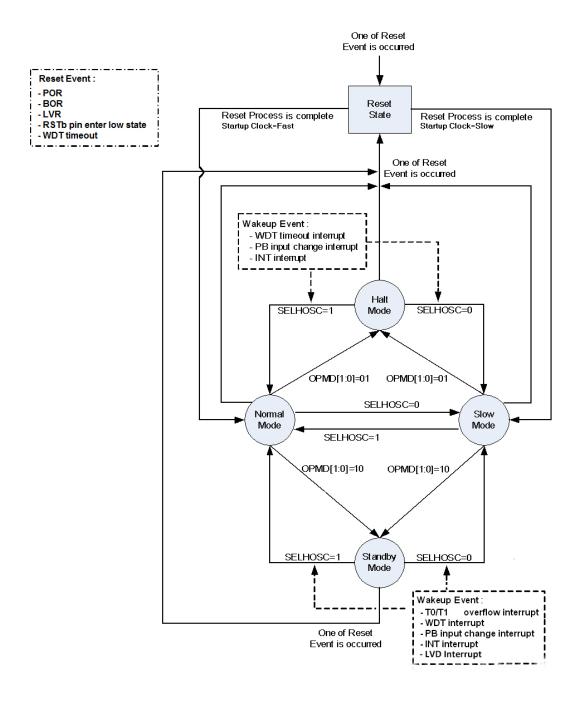


Figure 20 Four Operating Modes

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### 3.13.1 Normal Mode

After any Reset Event is occurred and Reset Process is complete, NY8A051H1 will begin to execute program under Normal mode or Slow mode. Which mode is selected after Reset Process is determined by the Startup Clock configuration word. If Startup Clock= I\_HRC, NY8A051H1 will enter Normal mode, if Startup Clock= I\_LRC, NY8A051H1 will enter Slow mode. At Normal mode, Fhose is selected as system oscillation in order to provide highest performance and its power consumption will be the largest among four



operating modes. After power on or any reset trigger is released, NY8A051H1 will enter Normal mode after reset process is complete.

Instruction execution is based on F<sub>HOSC</sub> and all peripheral modules may be active according to corresponding module enable bit.

The FLOSC is still active and running.

corresponding module enable bit.

IC can switch to Slow mode by writing 0 to register bit SELHOSC (OSCCR[0]).

IC can switch to Standby mode or Halt mode by programming register bits OPMD[1:0] (OSCCR[3:2]).

For real time clock applications, the NY8A051H1 can run in normal mode, at the same time the low-frequency clock. Low Oscillator Frequency connects to timer0 clock. This is made possible by setting LCKTM0 to 1 and corresponding configuration word Timer0 source setting to 1.

#### 3.13.2 Slow Mode

NY8A051H1 will enter Slow mode by writing 0 to register bit SELHOSC. At Slow mode, F<sub>LOSC</sub> is selected as system oscillation in order to save power consumption but still keep IC running. However, F<sub>HOSC</sub> will not be disabled automatically by NY8A051H1. Therefore user can write 0 to register bit STPHOSC (OSCCR[1]) in slow mode to reduce power consumption further. But it is noted that it is forbidden to enter slow mode and stop F<sub>HOSC</sub> at the same time, one must enter slow mode first, then disable F<sub>HOSC</sub>, or the program may hang on. Instruction execution is based on F<sub>LOSC</sub> and all peripheral modules may be active according to

FHOSC can be disabled by writing 1 to register bit STPHOSC.

IC can switch to Standby mode or Halt mode by programming register bits OPMD[1:0].

IC can switch to Normal mode by writing 1 to SELHOSC.

### 3.13.3 Standby Mode

NY8A051H1 will enter Standby mode by writing 10b to register bits OPMD[1:0]. At Standby mode, however, FHOSC will not be disabled automatically by NY8A051H1 and user has to enter slow mode and write 1 to register bit STPHOSC in order to stop FHOSC oscillation. Most of NY8A051H1 peripheral modules are disabled but Timer can be still active if register bit T0EN/T1EN is set to 1. Therefore NY8A051H1 can wake-up after Timer0/Timer1 is expired. The expiration period is determined by the register TMR0/TMR1, FINST and other configurations for Timer0/Timer1.

Instruction execution is stop and some peripheral modules may be active according to corresponding module enable bit.

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FHOSC can be disabled by writing 1 to register bit STPHOSC.

The FLOSC is still active and running.



IC can wake-up from Standby mode if any of (a) Timer0 overflow (b) Timer1 underflow interrupt, (c) WDT timeout interrupt, (d) PB input change interrupt or (e) INT external interrupt is happened, (f) LVD Interrupt.

After wake-up from Standby mode, IC will return to Normal mode if SELHOSC=1, IC will return to Slow mode if SELHOSC=0.

It is not recommended to change oscillator mode (normal to slow / slow to normal) and enter standby mode at the same time.

#### 3.13.4 Halt Mode

NY8A051H1 will enter Halt mode by executing instruction SLEEP or writing 01b to register bits OPMD[1:0]. After entering Halt mode, register bit /PD (STATUS[3]) will be clear to 0, register bit /TO (STATUS[4]) will be set to 1 and WDT will be clear but keep running.

At Halt mode, all of peripheral modules are disabled, instruction execution is stop and NY8A051H1 can only wake-up by some specific events. Therefore, Halt mode is the most power saving mode provided by NY8A051H1.

Instruction execution is stop and all peripheral modules are disabled.

FHOSC and FLOSC are both disabled automatically.

IC can wake-up from Halt mode if any of (a) WDT timeout interrupt, (b) PB input change interrupt or (c) INT or external interrupt is happened.

After wake-up from Halt mode, IC will return to Normal mode if SELHOSC=1, IC will return to Slow mode if SELHOSC=0.

Note: you can change STPHOSC and enter Halt mode in the same instruction.

It is not recommended to change oscillator mode (normal to slow / slow to normal) and enter standby mode at the same time

## 3.13.5 Wake-up Stable Time

The wake-up stable time of Halt mode is  $16*Fosc_7$  There is no need of wake-up stable time for Standby mode because either  $F_{HOSC}$  or  $F_{LOSC}$  is still running at Standby mode.

Before NY8A051H1 enters Standby mode or Halt mode, user may execute instruction ENI. At this condition, NY8A051H1 will branch to address 0x008 in order to execute interrupt service routine after wake-up. If instruction DISI is executed before entering Standby mode or Halt mode, the next instruction will be executed after wake-up.

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# 3.13.6 Summary of Operating Mode

The summary of four operating modes is described in the following table.

Mode	Normal	Slow	Standby	Halt
F <sub>HOSC</sub>	Enabled	STPHOSC	STPHOSC	Disabled
FLOSC	Enabled	Enabled	Enabled	Disabled
Instruction Execution	Executing	Executing	Stop	Stop
Timer0/1	T0EN / T1EN	T0EN / T1EN	T0EN / T1EN	Disabled
WDT	Option and	Option and	Option and	Option and
VVDT	WDTEN	WDTEN	WDTEN	WDTEN
Other Modules	Module enable bit	Module enable bit	Module enable bit	All disabled
Wake-up Source	-		- Timer0 overflow - Timer1 underflow - WDT timeout - PB input change - INT - LVD	- WDT timeout - PB input change - INT

Table 17 Summary of Operating Modes

### 3.14 Reset Process

NY8A051H1 will enter Reset State and start Reset Process when one of following Reset Event is occurred:

Power-On Reset (POR) is occurred when V<sub>DD</sub> rising is detected.

Low-Voltage Reset (LVR) is occurred when operating V<sub>DD</sub> is below pre-defined voltage.

Pin RSTb is low state.

WDT timeout reset.

Moreover, value of all registers will be initialized to their initial value or unchanged if its initial value is unknown. The status bits /TO and /PD could be initialized according to which event causes reset. The /TO and /PD value and its associated event is summarized in the table below.

Event	/TO	/PD
POR, LVR	1	1
RSTb reset from non-Halt mode	unchanged	unchanged
RSTb reset from Halt mode	1	1
WDT reset from non-Halt mode	0	1
WDT reset from Halt mode	0	0
SLEEP executed	1	0
CLRWDT executed	1	1

Table 18 Summary of /TO & /PD Value and its Associated Event

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After Reset Event is released, NY8A051H1 will start Reset Process. It will wait certain amount of period for oscillation stable no matter what kind of oscillator is adopted. This period is called power-up reset time and is determined by three-bit configuration words which can be 140u, 4.5ms, 18ms, 72ms or 288ms. After oscillator is stable, NY8A051H1 will wait further 16 clock cycles of FOSC (oscillator start-up time, OST) and Reset Process is complete.

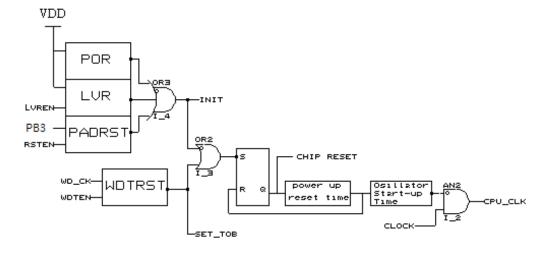


Figure 21 Block diagram of on-chip reset circuit

For slow VDD power-up, it is recommended to use RSTb reset, as the following figure.

It is recommended the R value should be not greater than  $40k\Omega$ .

The R1 value= $100\Omega$  to  $1k\Omega$  will prevent high current, ESD or Electrical overstress flowing into reset pin.

The diode helps discharge quickly when power down.

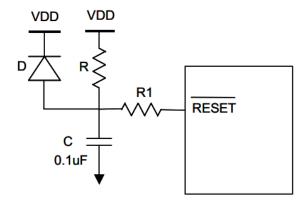


Figure 22 Block Diagram of Reset Application



# 4. Instruction Set

NY8A051H1 provides 55 powerful instructions for all kinds of applications.

	0	Р					OP			_	
Inst.	1	2	Operation	Cyc.	Flag	Inst.	1	2	Operation	Cyc.	Flag
Arithmetic Instructions			Arithme	Arithmetic Instructions							
ANDAR	R	d	dest = ACC & R	1	Z	ADDAR	R	d	dest = R + ACC	1	Z, DC, C
IORAR	R	d	dest = ACC   R	1	Z	SUBAR	R	d	dest = R + (~ACC)	1	Z, DC, C
XORAR	R	d	dest = ACC ⊕ R	1	Z	ADCAR	R	d	dest = R + ACC + C	1	Z, DC, C
ANDIA	i		ACC = ACC & i	1	Z	SBCAR	R	d	dest = R + (~ACC) + C	1	Z, DC, C
IORIA	i		ACC = ACC   i	1	Z	ADDIA	i		ACC = i + ACC	1	Z, DC, C
XORIA	i		ACC = ACC ⊕ i	1	Z	SUBIA	i		ACC = i + (~ACC)	1	Z, DC, C
RRR	R	d	Rotate right R	1	С	ADCIA	i		ACC = i + ACC + C	1	Z, DC, C
RLR	R	d	Rotate left R	1	С	SBCIA	i		ACC = i + (~ACC) + C	1	Z, DC, C
BSR	R	bit	Set bit in R	1	-	DAA			Decimal adjust for ACC	1	С
BCR	R	bit	Clear bit in R	1	-	CMPAR	R		Compare R with ACC	1	Z, C
INCR	R	d	Increase R	1	Z	CLRA			Clear ACC	1	Z
DECR	R	d	Decrease R	1	Z	CLRR			Clear R	1	Z
COMR	COMR         R         d         dest = ~R         1         Z		Other I	Other Instructions							
Conditio	nal	Insti	ructions			NOP			No operation	1	-
BTRSC	R	bit	Test bit in R, skip if clear	1 or 2	-	SLEEP			Go into Halt mode	1	/TO, /PD
BTRSS	R	bit	Test bit in R, skip if set	1 or 2	-	CLRWDT			Clear Watch-Dog Timer	1	/TO, /PD
INCRSZ	R	d	Increase R, skip if 0	1 or 2	-	ENI			Enable interrupt	1	-
DECRSZ	R	d	Decrease R, skip if 0	1 or 2	-	DISI			Disable interrupt	1	-
Data Tra	nsfe	er In	structions			INT			Software Interrupt	3	-
MOVAR	R		Move ACC to R	1	-	RET			Return from subroutine	2	-
MOVR	R	d	Move R	1	Z	RETIE			Return from interrupt	2	_
MOVIA	i		Move immediate to ACC	1	-				and enable interrupt		
SWAPR	R	d	Swap halves R	1	-	RETIA		i	Return, place immediate	2	_
IOST	F		Load ACC to F-page SFR	1	-	112117			in ACC		
IOSTR	F		Move F-page SFR to ACC	1	-	CALLA			Call subroutine by ACC	2	-
SFUN	Ø		Load ACC to S-page SFR	1	-	GOTOA			unconditional branch by ACC	2	1
SFUNR	S		Move S-page SFR to ACC	1	-	CALL	а	dr	Call subroutine	2	-
TOMD			Load ACC to T0MD	1	-	GOTO	а	dr	unconditional branch	2	1
T0MDR			Move T0MD to ACC	1	-	LCALL	а	dr	Call subroutine	2	-
TABLEA			Read ROM	2	-	LGOTO	а	dr	unconditional branch	2	-

Table 19 Instruction Set

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ACC: Accumulator.

adr: immediate address.

bit: bit address within an 8-bit register R.

C: Carry/Borrow bit

C=1, carry is occurred for addition instruction or borrow is **NOT** occurred for subtraction instruction.

C=0, carry is not occurred for addition instruction or borrow **IS** occurred for subtraction instruction.

d: Destination

If d is "0", the result is stored in the ACC.

If d is "1", the result is stored back in register R.

DC: Digital carry flag.

dest: Destination.

F: F-page SFR, F is  $0x5 \sim 0xF$ .

i: 8-bit immediate data.

PC: Program Counter.

PCHBUF: High Byte Buffer of Program Counter.

/PD: Power down flag bit

/PD=1, after power-up or after instruction CLRWDT is executed.

/PD=0, after instruction SLEEP is executed.

Prescaler: Prescaler0 dividing rate.

R: R-page SFR, R is 0x00 ~0x3F.

S: S-page SFR, S is  $0x0 \sim 0xF$ .

T0MD: T0MD register.

TBHP: The high-Byte at target address in ROM.

TBHD: Store the high-Byte data at target address in ROM.

/TO: Time overflow flag bit

/TO=1, after power-up or after instruction CLRWDT or SLEEP is executed.

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/TO=0, WDT timeout is occurred.

WDT: Watchdog Timer Counter.

Z: Zero flag.



ADCAR	Add ACC and R with Carry	ADDAR	Add ACC and R
Syntax:	ADCAR R, d	Syntax:	ADDAR R, d
Operand:	$0 \le R \le 63$	Operand:	0 ≤ R ≤63
	d = 0, 1.		d = 0, 1.
Operation:	R + ACC + C → dest	Operation:	ACC + R → dest
Status affected:	Z, DC, C	Status affected:	Z, DC, C
Description:	Add the contents of ACC and	Description:	Add the contents of ACC and R.
	register R with Carry. If d is 0, the		If d is 0, the result is stored in
	result is stored in ACC. If d is 1,		ACC. If d is 1, the result is
	the result is stored back to R.		stored back to R.
Cycle	1	Cycle:	1
Example:	ADCAR R, d	Example:	ADDAR R, d
	before executing instruction:		before executing instruction:
	ACC=0x12, R=0x34, C=1, d=1.		ACC=0x12, R=0x34,C=1, d=1.
	after executing instruction:		after executing instruction:
	R=0x47, ACC=0x12, C=0.		R=0x46, ACC=0x12, C=0.

ADCIA	Add ACC and Immediate with		
	Carry	ADDIA	Add ACC and Immediate
Syntax:	ADCIA i	Syntax:	ADDIA i
Operand:	0 ≤ i < 255	Operand:	0 ≤ i < 255
Operation:	$ACC + i + C \rightarrow ACC$	Operation:	$ACC + i \rightarrow ACC$
Status affected:	Z, DC, C	Status affected:	Z, DC, C
Description:	Add the contents of ACC and the	Description:	Add the contents of ACC with the
	8-bit immediate data i with		8-bit immediate data i. The
	Carry. The result is placed in		result is placed in ACC.
	ACC.	Cycle:	1
Cycle:	1	Example:	ADDIA i
Example:	ADCIA i		before executing instruction:
	before executing instruction:		ACC=0x12, i=0x34, C=1.
	ACC=0x12, i=0x34, C=1.		after executing instruction:
	after executing instruction:		ACC=0x46, C=0.
	ACC=0x47, C=0.		



ANDAR	AND ACC and R	BCR	Clear Bit in R
Syntax:	ANDAR R, d	Syntax:	BCR R, bit
Operand:	$0 \le R \le 63.$	Operand:	$0 \le R \le 63$
	d = 0, 1.		$0 \le \text{bit} \le 7$
Operation:	ACC & R → dest	Operation:	$0 \rightarrow R[bit]$
Status affected:	Z	Status affected:	
Description:	The content of ACC is AND'ed with	Description:	Clear the bit <sup>th</sup> position in R.
	R. If d is 0, the result is stored in	Cycle:	1
	ACC. If d is 1, the result is	Example:	BCR R,B2
	stored back to R.		before executing instruction:
Cycle:	1		R=0x5A, B2=0x3.
Example:	ANDAR R, d		after executing instruction:
	before executing instruction:		R=0x52.
	ACC=0x5A, R=0xAF, d=1.		
	after executing instruction:		
	R=0x0A, ACC=0x5A, Z=0.		

**BSR** 

ANDIA	AND Immediate with ACC	Syntax:	BSR R, bit
Syntax:	ANDIA i	Operand:	$0 \le R \le 63$
Operand:	0 ≤ i < 255		$0 \le bit \le 7$
Operation:	ACC & i→ACC	Operation:	$1 \rightarrow R[bit]$
Status affected:	Z	Status affected:	
Description:	The content of ACC register is	Description:	Set the bit <sup>th</sup> position in R.
	AND'ed with the 8-bit	Cycle:	1
	immediate data i. The result is	Example:	BSR R,B2
	placed in ACC.		before executing instruction:
Cycle:	1		R=0x5A, B2=0x2.
Example:	ANDIA i		after executing instruction:
	before executing instruction:		R=0x5E.
	ACC=0x5A, i=0xAF.		
	after executing instruction:		
	ACC=0x0A, Z=0.		

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Set Bit in R



BTRSC	Test Bit in R and Skip if Clear	BTRSS	Test Bit in R and Skip if Set
Syntax:	BTRSC R, bit	Syntax:	BTRSS R, bit
Operand:	$0 \le R \le 63$	Operand:	$0 \le R \le 63$
	$0 \le \text{bit} \le 7$		$0 \le bit \le 7$
Operation:	Skip next instruction, if R[bit] = 0.	Operation:	Skip next instruction, if R[bit] = 1.
Status affected:		Status affected:	
Description:	If R[bit] = 0, the next instruction	Description:	If R[bit] = 1, the next instruction
	which is already fetched is		which is already fetched is
	discarded and a NOP is		discarded and a NOP is
	executed instead. Therefore it		executed instead. Therefore it
	makes this instruction a		makes this instruction a
	two-cycle instruction.		two-cycle instruction.
Cycle:	1 or 2(skip)	Cycle:	1 or 2(skip)
Example:	BTRSC R, B2	Example:	BTRSS R, B2
	Instruction1		Instruction2
	Instruction2		Instruction3
	before executing instruction:		before executing instruction:
	R=0x5A, B2=0x2.		R=0x5A, B2=0x3.
	after executing instruction:		after executing instruction:
	because R[B2]=0, instruction1 will		because R[B2]=1, instruction2 will
	not be executed, the program		not be executed, the program
	will start execute instruction		will start execute instruction
	from instruction2.		from instruction3.



CALL	Call Subroutine	CALLA	Call Subroutine
Syntax:	CALL adr	Syntax:	CALLA
Operand:	0 ≤ adr < 255	Operand:	
Operation: Status affected: Description:	PC + 1 → Top of Stack {PCHBUF, adr} → PC   The return address (PC + 1) is   pushed onto top of Stack. The   8-bit immediate address adr is   loaded into PC[7:0] and   PCHBUF[1:0] is loaded into   PC[9:8].	Operation:  Status affected: Description:  Cycle:	PC + 1 → Top of Stack {TBHP, ACC} → PC The return address (PC + 1) is   pushed onto top of Stack. The   contents of TBHP[1:0] is loaded   into PC[9:8] and ACC is loaded   into PC[7:0].
Cycle: Example:	CALL SUB before executing instruction: PC=A0. Stack pointer=1 after executing instruction: PC=address of SUB, Stack[1] = A0+1, Stack pointer=2.	Example:	CALLA before executing instruction: TBHP=0x02, ACC=0x34. PC=A0. Stack pointer=1. after executing instruction: PC=0x234, Stack[1]=A0+1, Stack pointer=2.

Clear ACC
CLRA
$00h \rightarrow ACC$
1→ Z
Z
ACC is clear and Z is set to 1.
1
CLRA
before executing instruction:
ACC=0x55, Z=0.
after executing instruction:
ACC=0x00, Z=1.



CLRR	Clear R	COMR	Complement R
Syntax:	CLRR R	Syntax:	COMR R, d
Operand:	$0 \le R \le 63$	Operand:	$0 \le R \le 63$
Operation:	$00h \rightarrow R$		d = 0, 1.
	$1 \rightarrow Z$	Operation:	~R → dest
Status affected:	Z	Status affected:	Z
Description:	The content of R is clear and Z is	Description:	The content of R is complemented.
	set to 1.		If d is 0, the result is stored in
Cycle:	1		ACC. If d is 1, the result is
Example:	CLRR R		stored back to R.
	before executing instruction:	Cycle:	1
	R=0x55, Z=0.	Example:	COMR, d
	after executing instruction:		before executing instruction:
	R=0x00, Z=1.		R=0xA6, d=1, Z=0.
			after executing instruction:
			R=0x59, Z=0.

CLRWDT	Clear Watch-Dog Timer	CMPAR	Compare ACC and R
Syntax:	CLRWDT	Syntax:	CMPAR R
Operand:		Operand:	$0 \le R \le 63$
Operation:	$00h \rightarrow WDT$ ,	Operation:	R - ACC → (No restore)
	00h → WDT prescaler	Status affected:	Z, C
	1 →/TO	Description:	Compare ACC and R by
	1 →/PD		subtracting ACC from R with 2's
Status affected:	/TO, /PD		complement representation.
Description:	Executing CLRWDT will reset		The content of ACC and R is
	WDT, Prescaler0 if it is		not changed.
	assigned to WDT. Moreover,	Cycle:	1
	status bits /TO and /PD will be	Example:	CMPAR R
	set to 1.		before executing instruction:
Cycle:	1		R=0x34, ACC=12, Z=0, C=0.
Example:	CLRWDT		after executing instruction:
	before executing instruction:		R=0x34, ACC=12, Z=0, C=1.
	/TO=0		
	after executing instruction:		
	/TO=1		



DAA	Convert ACC Data Format from	DECR	Decrease R
	Hexadecimal to Decimal	Syntax:	DECR R, d
Syntax:	DAA	Operand:	$0 \le R \le 63$
Operand:			d = 0, 1.
Operation:	$ACC(hex) \rightarrow ACC(dec)$	Operation:	R - 1 → dest
Status affected:	С	Status affected:	Z
Description:	Convert ACC data format from	Description:	Decrease R. If d is 0, the result is
	hexadecimal to decimal after		stored in ACC. If d is 1, the
	addition operation and restore		result is stored back to R.
	result to ACC. DAA instruction	Cycle:	1
	must be placed immediately	Example:	DECR R, d
	after addition operation if		before executing instruction:
	decimal format is required.		R=0x01, d=1, Z=0.
	Please note that interrupt		after executing instruction:
	should be disabled before		R=0x00, Z=1.
	addition instruction and enabled		
	after DAA instruction to avoid		
	unexpected result.		
Cycle:	1		
Example:	DISI		
	ADDAR R,d		
	DAA		
	ENI		
	before executing instruction:		
	ACC=0x28, R=0x25, d=0.		
	after executing instruction:		
	ACC=0x53, C=0.		



DECRSZ	Decrease R, Skip if 0	DISI	Disable Interrupt Globally
Syntax:	DECRSZ R, d	Syntax:	DISI
Operand:	0 ≤ R ≤ 63	Operand:	
	d = 0, 1.	Operation:	Disable Interrupt, $0 \rightarrow GIE$
Operation:	R - 1 → dest,	Status affected:	
	Skip if result = 0	Description:	GIE is clear to 0 in order to disable
Status affected:			all interrupt requests.
Description:	Decrease R first. If d is 0, the result	Cycle:	1
	is stored in ACC. If d is 1, the	Example:	DISI
	result is stored back to R.		before executing instruction:
	If result is 0, the next instruction		GIE=1.
	which is already fetched is		After executing instruction:
	discarded and a NOP is		GIE=0.
	executed instead. Therefore it		
	makes this instruction a		
	two-cycle instruction.		
Cycle:	1 or 2(skip)		
Example:	DECRSZ R, d		
	instruction2	ENI	Enable Interrupt Globally
	instruction3	Syntax:	ENI
	before executing instruction:	Operand:	
	R=0x1, d=1, Z=0.	Operation:	Enable Interrupt, $1 \rightarrow GIE$
	after executing instruction:	Status affected:	
	R=0x0, Z=1, and instruction will	Description:	GIE is set to 1 in order to enable all
	skip instruction2 execution		interrupt requests.
	because the operation result is	Cycle:	1
	zero.	Example:	ENI
			before executing instruction:
			GIE=0.
			After executing instruction:
			GIE=1.

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GOTO	Unconditional Branch
Syntax:	GOTO adr
Operand:	0 ≤ adr < 511
Operation:	$\{PCHBUF, adr\} \rightarrow PC$
Status affected:	
Description:	GOTO is an unconditional branch
	instruction. The 9-bit immediate
	address adr is loaded into
	PC[8:0] and PCHBUF[1] is
	loaded into PC[9].
Cycle:	2
Example:	GOTO Level
	before executing instruction:
	PC=A0.
	after executing instruction:
	PC=address of Level.

INCR	Increase R
Syntax:	INCR R, d
Operand:	$0 \le R \le 63$
	d = 0, 1.
Operation:	R + 1 → dest.
Status affected:	Z
Description:	Increase R. If d is 0, the result is
	stored in ACC. If d is 1, the
	result is stored back to R.
Cycle:	1
Example:	INCR R, d
	before executing instruction:
	R=0xFF, d=1, Z=0.
	after executing instruction:
	R=0x00, Z=1.

GOTOA	Unconditional Branch
Syntax:	GOTOA
Operand:	
Operation:	$\{TBHP, ACC\} \rightarrow PC$
Status affected:	
Description:	GOTOA is an unconditional branch
	instruction. The content of
	TBHP[1:0] is loaded into
	PC[9:8] and ACC is loaded into
	PC[7:0].
Cycle:	2
Example:	GOTOA
	before executing instruction:
	PC=A0. TBHP=0x02, ACC=0x34.
	after executing instruction:
	PC=0x234.

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INCRSZ	Increase R, Skip if 0	INT	Software Interrupt
Syntax:	INCRSZ R, d	Syntax:	INT
Operand:	$0 \le R \le 63$	Operand:	
	d = 0, 1.	Operation:	PC + 1 $\rightarrow$ Top of Stack,
Operation:	$R + 1 \rightarrow dest,$		001h → PC
	Skip if result = 0	Status affected:	
Status affected:		Description:	Software interrupt. First, return
Description:	Increase R first. If d is 0, the result		address (PC + 1) is pushed
	is stored in ACC. If d is 1, the		onto the Stack. The address
	result is stored back to R.		0x001 is loaded into PC[9:0].
	If result is 0, the next instruction	Cycle:	3
	which is already fetched is	Example:	INT
	discarded and a NOP is		before executing instruction:
	executed instead. Therefore it		PC=address of INT code.
	makes this instruction a		after executing instruction:
	two-cycle instruction.		PC=0x01.
Cycle:	1 or 2(skip)		
Example:	INCRSZ R, d		
	instruction2,		
	instruction3.		
	before executing instruction:		
	R=0xFF, d=1, Z=0.		
	after executing instruction:	IORAR	OR ACC with R
	R=0x00, Z=1. And the program will	Syntax:	IORAR R, d
	skip instruction2 execution	Operand:	$0 \le R \le 63$
	because the operation result is		d = 0, 1.
	zero.	Operation:	ACC   R → dest
		Status affected:	Z
		Description:	OR ACC with R. If d is 0, the result
			is stored in ACC. If d is 1, the
			result is stored back to R.
		Cycle:	1
		Example:	IORAR R, d
			before executing instruction:
			R=0x50, ACC=0xAA, d=1, Z=0.
			after executing instruction:
			and excoding instruction.

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IORIA	OR Immediate with ACC	IOSTR	Move F-page SFR to ACC
Syntax:	IORIA i	Syntax:	IOSTR F
Operand:	0 ≤ i < 255	Operand:	$0 \le F \le 15$
Operation:	ACC   i→ACC	Operation:	F-page SFR → ACC
Status affected:	Z	Status affected:	
Description:	OR ACC with 8-bit immediate data	Description:	Move F-page SFR F to ACC.
	i. The result is stored in ACC.	Cycle:	1
Cycle:	1	Example:	IOSTR F
Example:	IORIA i		before executing instruction:
	before executing instruction:		F=0x55, ACC=0xAA.
	i=0x50, ACC=0xAA, Z=0.		after executing instruction:
	after executing instruction:		F=0x55, ACC=0x55.
	ACC=0xFA, Z=0.		

IOST	Load F-page SFR from ACC	LCALL	Call Subroutine
Syntax:	IOSTF	Syntax:	LCALL adr
Operand:	0 ≤ F≤ 15	Operand:	$0 \le adr \le 1023$
Operation:	ACC → F-page SFR	Operation:	PC + 1 $\rightarrow$ Top of Stack,
Status affected:	<del></del>		$adr \rightarrow PC[9:0]$
Description:	F-page SFR F is loaded by content	Status affected:	
·	of ACC.	Description:	The return address (PC + 1) is
Cycle:	1		pushed onto top of Stack. The
Example:	IOST F		10-bit immediate address adr is
·	before executing instruction:		loaded into PC[9:0].
	F=0x55, ACC=0xAA.	Cycle:	2
	after executing instruction:	Example:	LCALL SUB
	F=0xAA, ACC=0xAA.		before executing instruction:
			PC=A0. Stack level=1
			after executing instruction:
			PC=address of SUB, Stack[1]=
			A0+1, Stack pointer =2.

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LGOTO	Unconditional Branch
Syntax:	LGOTO adr
Operand:	$0 \le adr \le 1023$
Operation:	$adr \rightarrow PC[9:0].$
Status affected:	
Description:	LGOTO is an unconditional branch
	instruction. The 10-bit
	immediate address adr is
	loaded into PC[9:0].
Cycle:	2
Example:	LGOTO Level
	before executing instruction:
	PC=A0.
	after executing instruction:
	PC=address of Level.

MOVIA	Move Immediate to ACC
Syntax:	MOVIA i
Operand:	0 ≤ i < 255
Operation:	$i \rightarrow ACC$
Status affected:	
Description:	The content of ACC is loaded with
	8-bit immediate data i.
Cycle:	1
Example:	MOVIA i
	before executing instruction:
	i=0x55, ACC=0xAA.
	after executing instruction:
	ACC=0x55.

MOVAR	Move ACC to R
Syntax:	MOVAR R
Operand:	$0 \le R \le 63$
Operation:	ACC→R
Status affected:	
Description:	Move content of ACC to R.
Cycle:	1
Example:	MOVAR R
	before executing instruction:
	R=0x55, ACC=0xAA.
	after executing instruction:
	R=0xAA, ACC=0xAA.

MOVR	Move to ACC or R
Syntax:	MOVR R, d
Operand:	$0 \le R \le 63$
	d = 0, 1.
Operation:	$R \rightarrow dest$
Status affected:	Z
Description:	The content of R is move to
	destination. If d is 0, destination
	is ACC. If d is 1, destination is R
	and it can be used to check
	whether R is zero according to
	status flag Z after execution.
Cycle:	1
Example:	MOVR R, d
	before executing instruction:
	R=0x0, ACC=0xAA, Z=0, d=0.
	after executing instruction:
	R=0x0, ACC=0x00, Z=1.

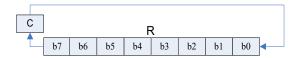


NOP	No Operation	RETIA	Return with Data in ACC
Syntax:	NOP	Syntax:	RETIA i
Operand:		Operand:	0 ≤ i < 255
Operation:	No operation.	Operation:	$i \rightarrow ACC$ ,
Status affected:			Top of Stack → PC
Description:	No operation.	Status affected:	
Cycle: Example:	NOP before executing instruction: PC=A0 after executing instruction: PC=A0+1	Description:  Cycle: Example:	ACC is loaded with 8-bit immediate data i and PC is loaded from top of Stack as return address and GIE is set to 1.  RETIA i before executing instruction: Stack pointer =2, i=0x55, ACC=0xAA. after executing instruction: PC=Stack[2], Stack pointer =1, ACC=0x55.

Return from Interrupt and		
Enable Interrupt Globally	RET	Return from Subroutine
RETIE	Syntax:	RET
	Operand:	
Top of Stack $\rightarrow$ PC	Operation:	Top of Stack → PC
1→GIE	Status affected:	
	Description:	PC is loaded from top of Stack as
The PC is loaded from top of Stack		return address.
as return address and GIE is	Cycle:	2
set to 1.	Example:	RET
2		before executing instruction:
RETIE		Stack level=2.
before executing instruction:		after executing instruction:
GIE=0, Stack level=2.		PC=Stack[2], Stack level=1.
after executing instruction:		
GIE=1, PC=Stack[2], Stack level		
=1.		
	Enable Interrupt Globally  RETIE   Top of Stack → PC  1 → GIE   The PC is loaded from top of Stack     as return address and GIE is     set to 1.  2  RETIE  before executing instruction:  GIE=0, Stack level=2.  after executing instruction:  GIE=1, PC=Stack[2], Stack level	Enable Interrupt Globally RET   RETIE Syntax:   Operand:   Top of Stack → PC Operation:   1 → GIE Status affected:   Description:   The PC is loaded from top of Stack as return address and GIE is set to 1. Cycle:   2 Example:   RETIE before executing instruction:   GIE=0, Stack level=2. after executing instruction:   GIE=1, PC=Stack[2], Stack level



RLR	Rotate Left R Through Carry
Syntax:	RLR R, d
Operand:	$0 \le R \le 63$
	d = 0, 1.
Operation:	$C \rightarrow dest[0], R[7] \rightarrow C,$
	$R[6:0] \rightarrow dest[7:1]$



Status affected: C

Description: The content of R is rotated one bit

to the left through flag Carry. If d is 0, the result is placed in ACC.

If d is 1, the result is stored

back to R.

Cycle: 1

Example: RLR R, d

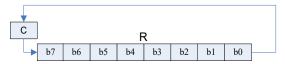
before executing instruction:

R=0xA5, d=1, C=0.

after executing instruction:

R=0x4A, C=1.

RRR	Rotate Right R Through Carry
Syntax:	RRR R, d
Operand:	$0 \le R \le 63$
	d = 0, 1.
Operation:	$C \rightarrow dest[7], R[7:1] \rightarrow dest[6:0],$
	$R[0] \rightarrow C$



Status affected: C

Description: The content of R is rotated one bit

to the right through flag Carry. If d is 0, the result is placed in ACC. If d is 1, the result is

stored back to R.

Cycle: 1

Example: RRR R, d

before executing instruction:

R=0xA5, d=1, C=0.

after executing instruction:

R=0x52, C=1.



SBCAR	Subtract ACC and Carry from R	SBCIA	Subtract ACC and Carry from
Syntax:	SBCAR R, d		Immediate
Operand:	$0 \le R \le 63$	Syntax:	SBCIA i
	d = 0, 1.	Operand:	0 ≤ i < 255
Operation:	$R + (\sim ACC) + C \rightarrow dest$	Operation:	i + (~ACC) + C → dest
Status affected:	Z, DC, C	Status affected:	Z, DC, C
Description:	Subtract ACC and Carry from R	Description:	Subtract ACC and Carry from 8-bit
	with 2's complement		immediate data i with 2's
	representation. If d is 0, the		complement representation.
	result is placed in ACC. If d is 1,		The result is placed in ACC.
	the result is stored back to R.	Cycle:	1
Cycle:	1	Example:	SBCIA i
Example:	SBCAR R, d		(a) before executing instruction:
	(a) before executing instruction:		i=0x05, ACC=0x06, C=0.
	R=0x05, ACC=0x06, d=1, C=0.		after executing instruction:
	after executing instruction:		ACC=0xFE, C=0. (-2)
	R=0xFE, C=0. (-2)		(b) before executing instruction:
	(b) before executing instruction:		i=0x05, ACC=0x06, C=1.
	R=0x05, ACC=0x06, d=1, C=1.		after executing instruction:
	after executing instruction:		ACC=0xFF, C=0. (-1)
	R=0xFF, C=0. (-1)		(c) before executing instruction:
	(c) before executing instruction:		i=0x06, ACC=0x05, C=0.
	R=0x06, ACC=0x05, d=1, C=0.		after executing instruction:
	after executing instruction:		ACC=0x00, C=1. (-0), Z=1.
	R=0x00, C=1. (-0), Z=1.		(d) before executing instruction:
	(d) before executing instruction:		i=0x06, ACC=0x05, C=1.
	R=0x06, ACC=0x05, d=1, C=1.		after executing instruction:
	after executing instruction:		ACC=0x1, C=1. (+1)
	R=0x1, C=1. (+1)		



SFUN	Load S-page SFR from ACC	SLEEP	Enter Halt Mode
Syntax:	SFUN S	Syntax:	SLEEP
Operand:	0 ≤ S ≤15	Operand:	
Operation:	ACC → S-page SFR	Operation:	$00h \rightarrow WDT$ ,
Status affected:			00h → WDT prescaler
Description:	S-page SFR S is loaded by content		1 →/TO
	of ACC.		$0 \rightarrow /PD$
Cycle:	1	Status affected:	/TO, /PD
Example:	SFUN S	Description:	WDT and Prescaler0 are clear to 0.
	before executing instruction:		/TO is set to 1 and /PD is clear
	S=0x55, ACC=0xAA.		to 0.
	after executing instruction:		IC enter Halt mode.
	S=0xAA, ACC=0xAA.	Cycle:	1
		Example:	SLEEP
			before executing instruction:
			/PD=1, /TO=0.
			after executing instruction:
			/PD=0, /TO=1.

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SFUNR	Move S-page SFR to ACC
Syntax:	SFUNR S
Operand:	$0 \le S \le 15$
Operation:	S-page SFR → ACC
Status affected:	<del></del>
Description:	Move S-page SFR S to ACC.
Cycle:	1
Example:	SFUNR S
	before executing instruction:
	S=0x55, ACC=0xAA.
	after executing instruction:
	S=0x55, ACC=0x55.



SUBAR	Subtract ACC from R	SUBIA	Subtract ACC from Immediate
Syntax:	SUBAR R, d	Syntax:	SUBIA i
Operand:	$0 \le R \le 63$	Operand:	0 ≤ i < 255
	d = 0, 1.	Operation:	$i - ACC \rightarrow ACC$
Operation:	$R - ACC \rightarrow dest$	Status affected:	Z, DC, C
Status affected:	Z, DC, C	Description:	Subtract ACC from 8-bit immediate
Description:	Subtract ACC from R with 2's		data i with 2's complement
	complement representation. If d		representation. The result is
	is 0, the result is placed in ACC.		placed in ACC.
	If d is 1, the result is stored	Cycle:	1
	back to R.	Example:	SUBIA i
Cycle:	1		(a) before executing instruction:
Example:	SUBAR R, d		i=0x05, ACC=0x06.
	(a) before executing instruction:		after executing instruction:
	R=0x05, ACC=0x06, d=1.		ACC=0xFF, C=0. (-1)
	after executing instruction:		(b) before executing instruction:
	R=0xFF, C=0. (-1)		i=0x06, ACC=0x05, d=1.
	(b) before executing instruction:		after executing instruction:
	R=0x06, ACC=0x05, d=1.		ACC=0x01, C=1. (+1)
	after executing instruction:		
	R=0x01, C=1. (+1)		
		SWAPR	Swap High/Low Nibble in R
		Syntax:	SWAPR R.d.

SWAPR	Swap High/Low Nibble in R	
Syntax:	SWAPR R, d	
Operand:	$0 \le R \le 63$	
	d = 0, 1.	
Operation:	R[3:0] → dest[7:4].	
	R[7:4] → dest[3:0]	
Status affected:		
Description:	The high nibble and low nibble of R	
	is exchanged. If d is 0, the	
	result is placed in ACC. If d is 1,	
	the result is stored back to R.	
Cycle:	1	
Example:	SWAPR R, d	
	before executing instruction:	
	R=0xA5, d=1.	
	after executing instruction:	
	R=0x5A.	
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TABLEA	Read ROM data	T0MDR	Move T0MD to ACC
Syntax:	TABLEA	Syntax:	TOMDR
Operand:		Operand:	<del></del>
Operation:	ROM data{ TBHP, ACC } [7:0]	Operation:	$TOMD \rightarrow ACC$
- 1	→ACC	Status affected:	
	ROM data{TBHP, ACC} [13:8]	Description:	Move the content of T0MD to ACC.
	→TBHD.	Cycle:	1
Status affected:	<del></del>	Example:	T0MDR
Description:	The 8 least significant bits of ROM		before executing instruction
Bootinpuon.	pointed by {TBHP[2:0], ACC} is		T0MD=0x55, ACC=0xAA.
	placed to ACC.		after executing instruction
	The 6 most significant bits of ROM		ACC=0x55.
	pointed by {TBHP[2:0], ACC} is		
	placed to TBHD[5:0].		
Cycle:	2		
Example:	TABLEA		
·	before executing instruction:		
	TBHP=0x02, CC=0x34.		
	TBHD=0x01.		
	ROM data[0x234]= 0x35AA	XORAR	Exclusive-OR ACC with R
	after executing instruction:	Syntax:	XORAR R, d
	TBHD=0x35, ACC=0xAA.	Operand:	$0 \le R \le 63$
			d = 0, 1.
		Operation:	ACC⊕R→dest
T0MD	Load ACC to T0MD	Status affected:	Z
Syntax:	TOMD	Description:	Exclusive-OR ACC with R. If d is 0,
Operand:			the result is placed in ACC. If d
Operation:	ACC→ T0MD		is 1, the result is stored back to
Status affected:			R.
Description:	The content of T0MD is loaded by	Cycle:	1
	ACC.	Example:	XORAR R, d
			before executing instruction:
Cycle:	1		D-0vAE ACC-0vF0 d-4
Cycle: Example:	1 T0MD		R=0xA5, ACC=0xF0, d=1.
•			after executing instruction:
•	T0MD		
•	T0MD before executing instruction:		after executing instruction:



XORIA Exclusive-OR Immediate with

**ACC** 

Syntax: XORIA i

Operand:  $0 \le i < 255$ 

Operation:  $ACC \oplus i \rightarrow ACC$ 

Status affected: Z

Description: Exclusive-OR ACC with 8-bit

immediate data i. The result is

stored in ACC.

Cycle: 1

Example: XORIA i

before executing instruction:

i=0xA5, ACC=0xF0.

after executing instruction:

ACC=0x55.

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# 5. Configuration Words

Item	Name	Options
1	High IRC Frequency	1. 1MHz 2. 2MHz 3. 4MHz
'	riigit into Frequency	4. 8MHz 5. 16MHz 6. 20MHz
2	Instruction Clock	1. 2 oscillator period 2. 4 oscillator period
3	WDT	Watchdog Enable (Software control)
		Watchdog Disable (Always disable)
4	WDT Event	Watchdog Reset
5	Timer0 source	1. EX_CKI 2. I_LRC
6	PB.0	CMP analog input     2. Digital input
7	PB.1	CMP analog input     2. Digital input
8	PB.2	1. PB.2 is I/O 2. PB.2 is PWM 3. PB.2 is Buzzer
9	PB.3	1. PB.3 is I/O 2. PB.3 is reset
10	PB.4	PB.4 is I/O     PB.4 is instruction clock output
11	Startup Time	1. 140us 2. 4.5ms 3. 18ms 4. 72ms 5. 288ms
12	WDT Time Base	1. 3.5ms 2. 15ms 3. 60ms 4. 250ms
13	LVR Setting	Register Control     Register Control + Halt mode Off
13	LVN Setting	3. Always On 4. Operation mode On + Halt mode Off
14	LVR Voltage	1. 1.6V 2. 1.8V 3. 2.0V 4. 2.2V 5. 2.4V
		6. 2.7V 7. 3.0V 8. 3.3V 9. 3.6V 10. 4.2V
15	VDD Voltage	1. 3.0V 2. 4.5V 3. 5.0V
16	Read Output Data	1. I/O port 2. Register
17	EX_CKI to Inst. Clock	1. Sync 2. Async
18	Startup Clock	1. I_HRC 2. I_LRC
19	Input High Voltage (VIH)	1. 0.8VDD 2. 0.6VDD
20	Input Low Voltage (VIL)	1. 0.3VDD 2. 0.2VDD
21	Input Voltage Schmitt Trigger	1. Enable (depend on 17, 18) 2. Disable (17, 18 no use)
22	Sink / Drive Current	1. Small 2. Normal

Table 20 Configuration Words

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### 6. Electrical Characteristics

# 6.1 Absolute Maximum Rating

Symbol	Parameter	Rated Value	Unit
V <sub>DD</sub> - V <sub>SS</sub>	Supply voltage	-0.5 ~ +6.0	V
Vin	Input voltage	$V_{SS}$ -0.3 $V \sim V_{DD}$ +0.3	V
T <sub>OP</sub>	Operating Temperature	-40 ~ +85	°C
Tst	Storage Temperature	-40 ~ +125	°C

### 6.2 DC Characteristics

(All refer F<sub>INST</sub>=F<sub>HOSC</sub>/4, F<sub>HOSC</sub>=16MHz@I\_HRC, WDT enabled, ambient temperature T<sub>A</sub>=25°C unless otherwise specified.)

Symbo I	Parameter	V <sub>DD</sub>	Min.	Тур.	Max.	Unit	Condition	
			3.0			F <sub>INST</sub> =20MHz @ I_HRC/2		
			2.2				F <sub>INST</sub> =20MHz @ I_HRC/4	
			2.7				FINST=16MHz @ I_HRC/2	
$V_{\text{DD}}$	Operating voltage		2.0		5.5	V	F <sub>INST</sub> =16MHz @ I_HRC/4	
			2.0				FINST=8MHz @ I_HRC/4 & I_HRC/2	
			1.6				F <sub>INST</sub> =4MHz @ I_HRC/4 & I_HRC/2	
			1.6				F <sub>INST</sub> =32KHz @ I_LRC/4 & I_LRC/2	
		5V	4.0			V	RSTb (0.8V <sub>DD</sub> )	
		3V	2.4			V	(0.0Vbb)	
		5V	3.5			V	All other I/O pins, EX_CKI, INT	
VIII	V <sub>IH</sub> Input high voltage	3V	2.1			V	0.8V <sub>DD</sub>	
VIH		5V	2.5			V	All other I/O pins, EX_CKI, INT	
		3V	1.5			V	0.6V <sub>DD</sub>	
		5V		2.5		V	All other I/O pins, EX_CKI, INT	
		3V		1.5		V	No Schmitt Trigger (0.5V <sub>DD</sub> )	
		5V			1.0	V	RSTb (0.2V <sub>DD</sub> )	
		3V			0.6	v	(0.2 vbb)	
		5V			1.5	V	All other I/O pins, EX_CKI, INT	
VIL	Input low voltage	3V			0.9	V	0.3V <sub>DD</sub>	
VIL	input low voltage	5V			1.0	V	All other I/O pins, EX_CKI, INT	
		3V			0.6	v	0.2V <sub>DD</sub>	
		5V		2.5		V	All other I/O pins, EX_CKI, INT	
		3V		1.5		v	No Schmitt Trigger (0.5V <sub>DD</sub> )	
Іон	Output high current	5V		2.2		mA	V <sub>OH</sub> =4.0V	
IUH	(Small current)	3V		1.2		111/	V <sub>OH</sub> =2.0V	

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Symbo	Parameter	<b>V</b> <sub>DD</sub>	Min.	Тур.	Max.	Unit	Condition	
ı								
	Output high current	5V		20		mA	V <sub>OH</sub> =4.0V	
	(Normal current)	3V		12			V <sub>OH</sub> =2.0V	
	Output low current	5V		7.8		mA	V <sub>OL</sub> =1.0V	
I <sub>OL</sub>	(Small current)	3V		4.5				
	Output low current	5V		42		mA	V <sub>OL</sub> =1.0V	
	(Normal current)	3V		26			102 110	
I <sub>IR</sub>	IR sink current	5V		45		mA	V <sub>OL</sub> =1.0V, Normal IR	
1111	ii Comit carront	3V		26		1117 (	Vol. 1.0 v, Normal II v	
						No	ormal Mode	
		5V		1.7		mA	F <sub>HOSC</sub> =20MHz @ I_HRC/2	
		3V		0.7		IIIA	PHOSC-201VIII 2 @ I_IINO/2	
		5V		1.4		Л	F -20MU- @ LUDC/4	
		3V		0.5		mA	F <sub>HOSC</sub> =20MHz @ I_HRC/4	
		5V		1.5			F 40MH- 0 L HP0/0	
		3V		0.6		mA	F <sub>HOSC</sub> =16MHz @ I_HRC/2	
		5V		1.3			- 40444 0 4 4 1 1 1 1 1 1 1 1 1 1 1 1 1 1	
		3V		0.5		mA	F <sub>HOSC</sub> =16MHz @ I_HRC/4	
		5V		1.2			5 01111 0 1 1150/2	
		3V		0.4		mA	FHOSC=8MHz @ I_HRC/2	
		5V		0.9			5 0144 0 1 11704	
		3V		0.3		mA	FHOSC=8MHz @ I_HRC/4	
IOP	Operating current	5V		0.8			5 4444 0 1 1170/0	
		3V		0.3		mA	F <sub>HOSC</sub> =4MHz @ I_HRC/2	
		5V		0.7			5 4444 0 1 11704	
		3V		0.2		mA	F <sub>HOSC</sub> =4MHz @ I_HRC/4	
		5V		0.5			- 4444 0 4 4750/2	
		3V		0.2		mA	F <sub>HOSC</sub> =1MHz @ I_HRC/2	
		5V		0.5				
		3V		0.2		mA	F <sub>HOSC</sub> =1MHz @ I_HRC/4	
						S	low mode	
		5V		9.9			F <sub>HOSC</sub> disabled,	
		3V		4.9		uA	F <sub>LOSC</sub> =32KHz @ I_LRC/2	
		5V		6.6			F <sub>HOSC</sub> disabled,	
		3V		3.6		uA	FLOSC=32KHz @ I_LRC/4	
I <sub>STB</sub>	Standby current	5V		3.5		uA	Standby mode, F <sub>HOSC</sub> disabled,	
				•			.,,	

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Symbo	Parameter	V <sub>DD</sub>	Min.	Тур.	Max.	Unit	Condition	
		3V		2.5			FLOSC=32KHz @ I_LRC/4	
		5V		-	0.5		Halt made, WDT disabled	
lua =	Halt current	3V			0.2	uA	Halt mode, WDT disabled.	
IHALI	I <sub>HALT</sub> Halt current	5V		-	5.0	uA	Halt made, WDT anabled	
		3V			3.0	uA	Halt mode, WDT enabled.	
		5V		65		kΩ	Pull-High resistor (not include PB3)	
R <sub>PH</sub>	Pull-High resistor	3V		120		N12	Full-High resistor (not include FB3)	
INPH	rull-i ligit tesistoi	5V		85		kΩ	Dull High register (DR2)	
		3V		85		K12	Pull-High resistor (PB3)	
D	Pull-Low resistor	5V		55		kΩ	Pull-Low resistor	
R <sub>PL</sub>	Full-Low resistor	3V		105		K12	Full-Low resistor	

### 6.3 OSC Characteristic

Measurement conditions  $V_{\text{DD}}$  Voltage,  $T_{\text{A}}$  Temperature are equal to programming conditions.)

Parameter	Min.	Тур.	Max.	Unit	Condition
I_HRC deviation by socket			±1	%	Socket installed directly on writer.
I_HRC deviation by handler			±3	%	Handler condition with correct setup.
I_LRC deviation by handler			±5	%	

## 6.4 Comparator / LVD Characteristics

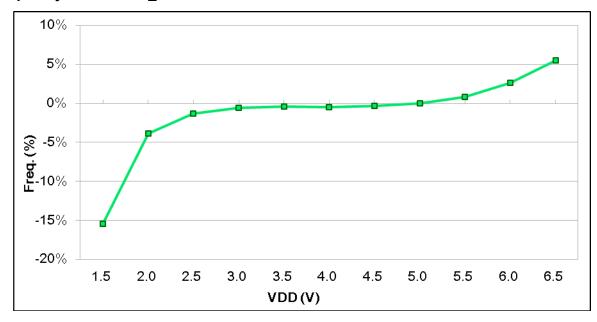
( $V_{DD}$ =5V,  $V_{SS}$ =0V,  $T_A$ =25°C unless otherwise specified.)

Symbol	Parameter	Min.	Тур.	Max.	Unit	Condition
V <sub>IVR</sub>	Comparator input voltage range	0		VDD-1.5	٧	F <sub>HOSC</sub> =1MHz
T <sub>ENO</sub>	Comparator enable to output valid		20		us	F <sub>HOSC</sub> =1MHz
Ico	Operating current of comparator		70		uA	F <sub>HOSC</sub> =1MHz, P2V mode
I <sub>LVD</sub>	Operating current of LVD		85		uA	F <sub>HOSC</sub> =1MHz, LVD=4.15V
E <sub>LVD</sub>	LVD voltage error			5	%	F <sub>HOSC</sub> =1MHz, LVD=4.15V
CPos	Comparator offset		10	20	mV	

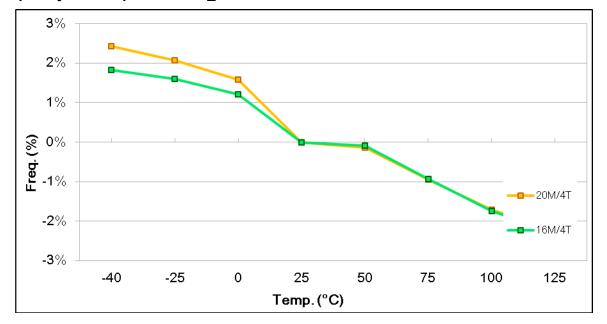


## 6.5 Characteristic Graph

## 6.5.1 Frequency vs. VDD of I\_HRC



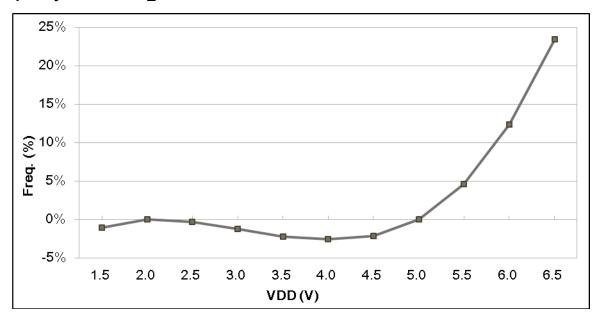
# 6.5.2 Frequency vs. Temperature of I\_HRC



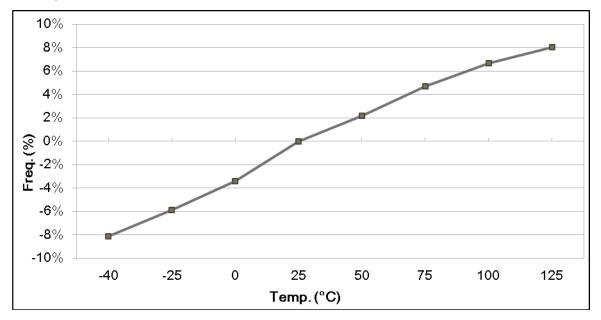
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# 6.5.3 Frequency vs. VDD of I\_LRC



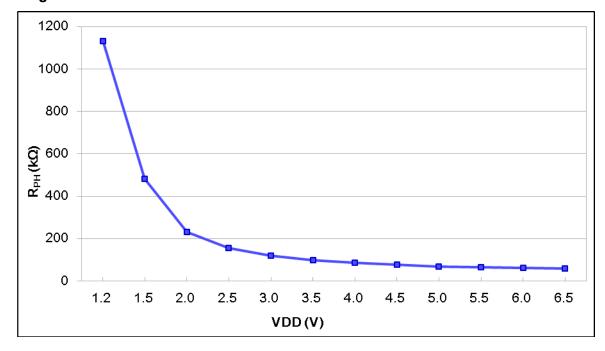
## 6.5.4 Frequency vs. Temperature of I\_LRC



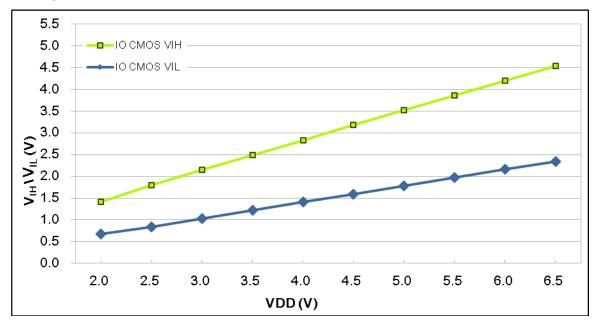
79



# 6.5.5 Pull High Resistor vs. VDD

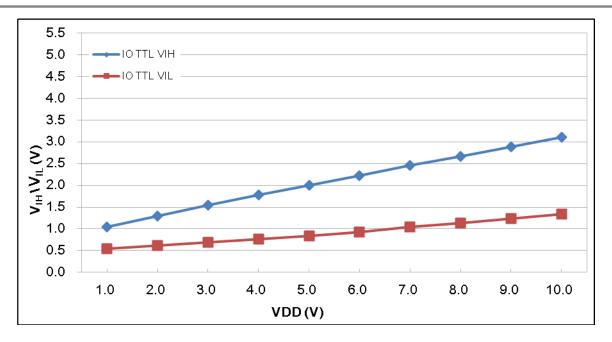


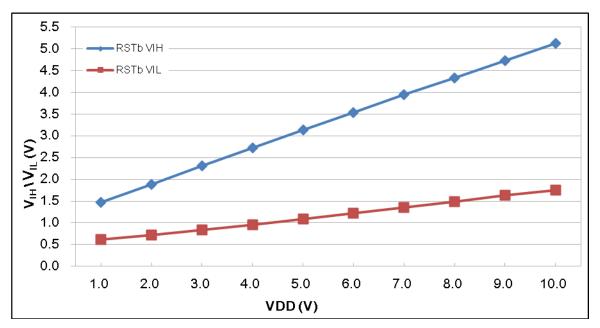
### 6.5.6 VIH/VIL vs. VDD



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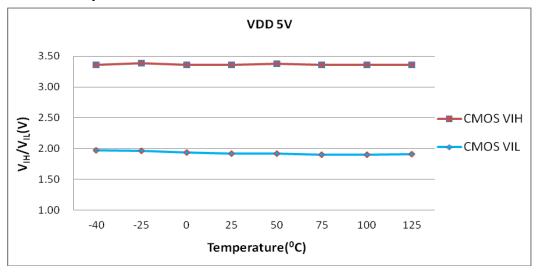


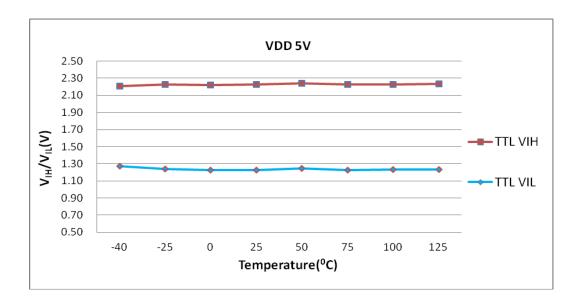


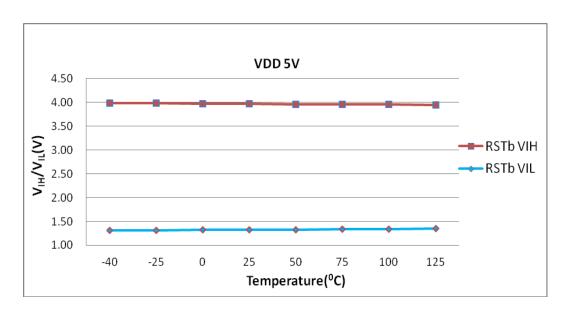
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## 6.5.7 VIH/VIL vs. Temperature







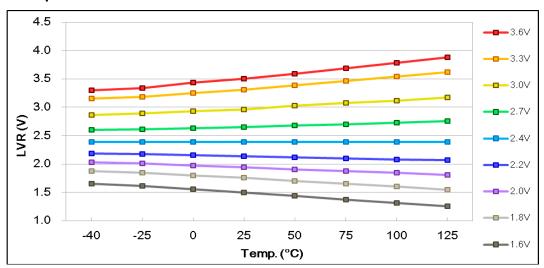


### 6.6 Recommended Operating Voltage

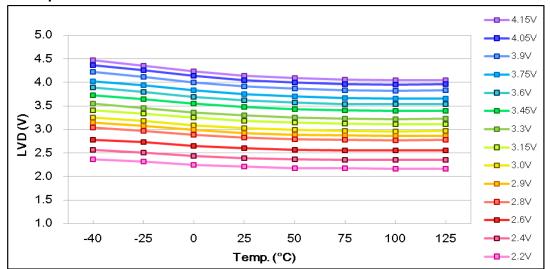
Recommended Operating Voltage (Temperature range: -40 °C ~ +85 °C)

Frequency	Min. Voltage	Max. Voltage	LVR : default ( 25 °C)	LVR : Recommended (-40 °C ~ +85 °C)
20M/2T	3.0V	5.5V	3.3V	3.6V
16M/2T	2.7V	5.5V	2.7V	3.0V
20M/4T	2.2V	5.5V	2.2V	2.4V
16M/4T	2.0V	5.5V	2.0V	2.2V
8M/2T	2.0V	5.5V	2.0V	2.2V
≤4M(2T or 4T)	1.6V	5.5V	1.6V	1.8V

# 6.7 LVR vs. Temperature



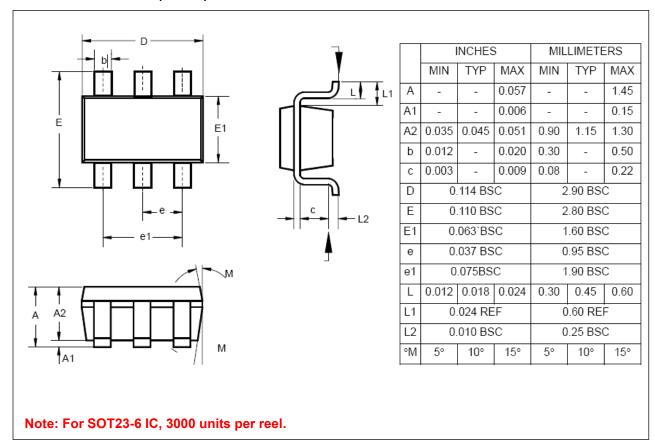
### 6.8 LVD vs. Temperature





# 7. Package Dimension

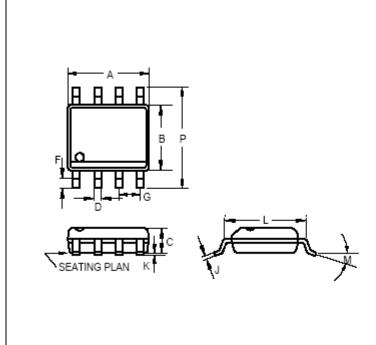
### 7.1 6-Pin Plastic SOT23-6 (63 mil)



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# 7.2 8-Pin Plastic SOP (150 mil)



	ı	NCHES	6	MILLIMETERS				
	MIN	TYP	MAX	MIN	TYP	MAX		
Α	0.183	-	0.202	4.65	-	5.13		
В	0.144	-	0.163	3.66	,	4.14		
С	0.068	-	0.074	1.35	-	1.88		
D	0.010	-	0.020	0.25	-	0.51		
F	0.015	,	0.035	0.38	,	0.89		
G	0.	050 BS	C	1.27 BSC				
J	0.007	-	0.010	0.19	-	0.25		
к	0.005	-	0.010	0.13	-	0.25		
L	0.189	-	0.205	4.80	_	5.21		
М	_	-	8°	-	_	8°		
Р	0.228	-	0.244	5.79	-	6.20		

Note: For 8-pin SOP, 100 units per tube.

# 8. Ordering Information

P/N	Package Type	Pin Count	Package Width	Shipping
NY8A051H1	Die			-
NY8A051H1S6	SOT23-6	6	63 mil	Tape & Reel: 3.0K pcs per Reel
NY8A051H1S8	SOP	8	150 mil	Tape & Reel: 2.5K pcs per Reel Tube: 100 pcs per Tube

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